

Reinventing Electronics for Energy-Efficient and Trustworthy Embedded AI

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How Far Will AI Energy Consumption Grow?



World ▾ Business ▾ Markets ▾ Sustainability ▾ Legal ▾ More ▾

Technology

OpenAI CEO Altman says at Davos future AI depends on energy breakthrough

Reuters

January 16, 2024 6:39 PM GMT+1 · Updated 2 months ago



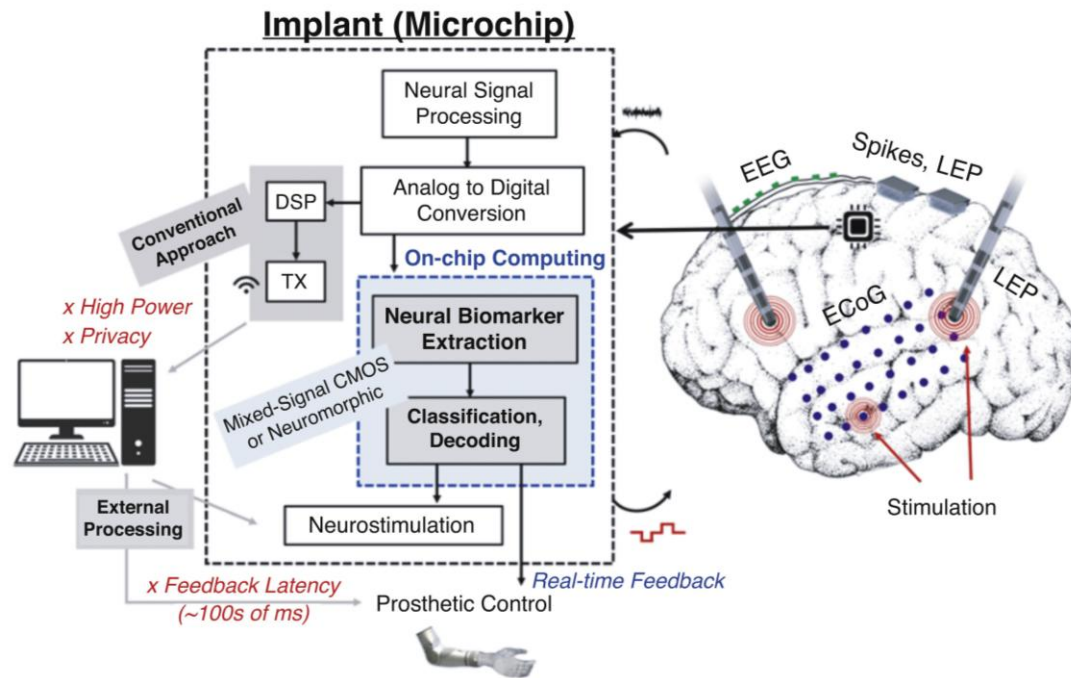
Sam Altman, CEO of OpenAI, attends the Asia-Pacific Economic Cooperation (APEC) CEO Summit in San Francisco, California, U.S. November 16, 2023. REUTERS/Carlos Barria/File Photo [Purchase Licensing Rights](#)

DAVOS, Switzerland, Jan 16 (Reuters) - OpenAI's CEO Sam Altman on Tuesday said an energy breakthrough is necessary for future artificial intelligence, which will consume vastly more power than people have expected.

Speaking at a Bloomberg event on the sidelines of the World Economic Forum's annual meeting in Davos, Altman said the silver lining is that more climate-friendly sources of energy, particularly nuclear fusion or cheaper solar power and storage, are the way forward for AI.

Or can we make AI *dramatically* more energy efficient?

AI Energy Inefficiency Limits Its Best Applications



Yoo and Shoaran,
Current Opinion Biotechnol., 2021

- Edge AI implemented in a medical implant could allow epilepsy prediction, advanced BMI...
- But currently limited to *elementary* AI

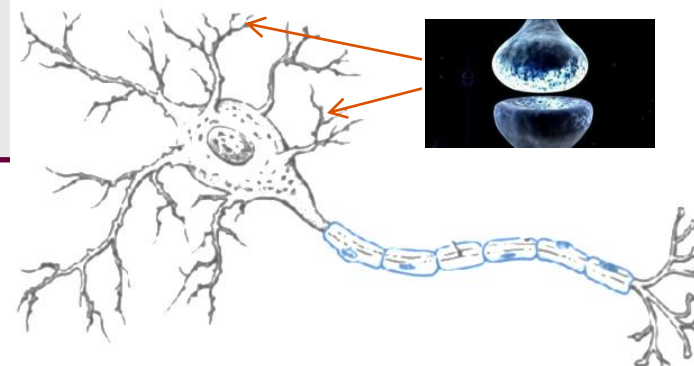
The AI Energy Problem Is a *Memory* Problem

- Neural networks: not a lot of arithmetics, but **Huge volume of parameters**
- In computers, GPUs, and AI accelerators developed by industry (Google TPU, Apple NPU...), memory access is extremely costly

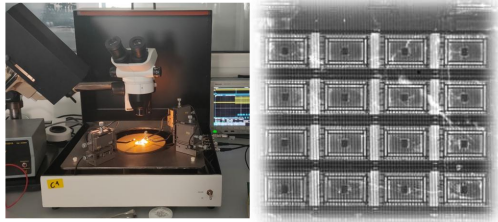
Operation	Energy
Addition of data (fixed point)	1x
Access data (onchip cache)	60x
Access data (offchip main memory)	3500x

Pedram et al , IEEE D&T 2016

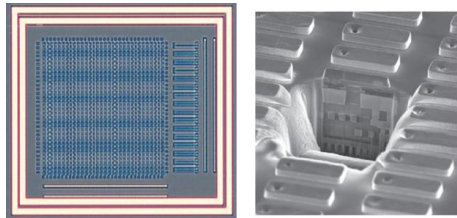
Absent in the brain!



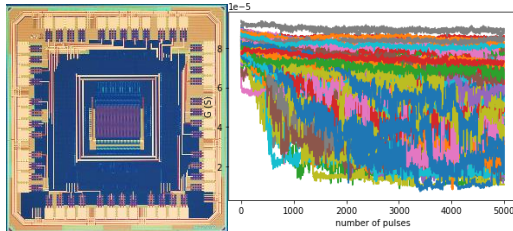
Toward Energy-Efficient and Trustworthy Embedded AI: The In-Memory Computing Approach



- Cointegrating Logic & Memory for Low-Energy AI

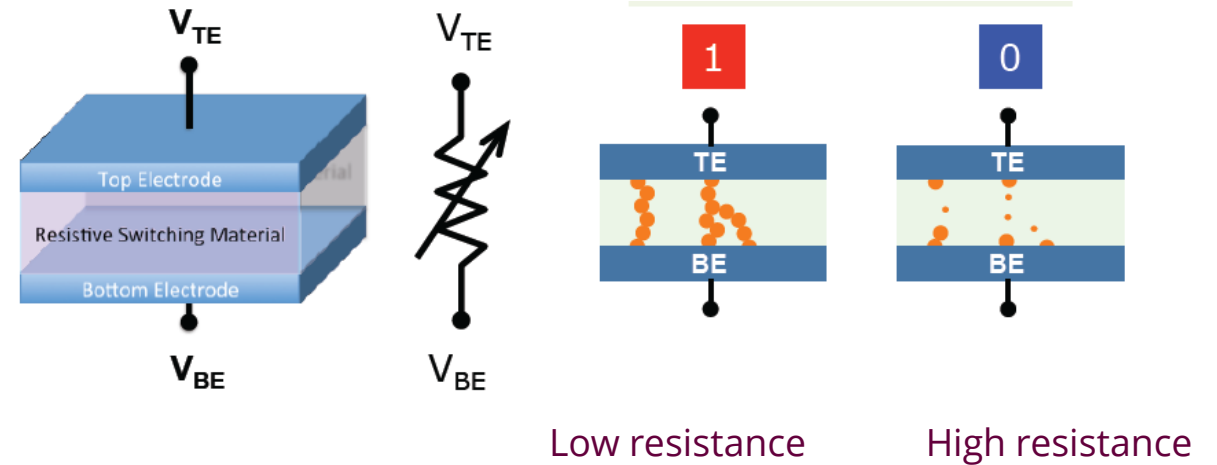
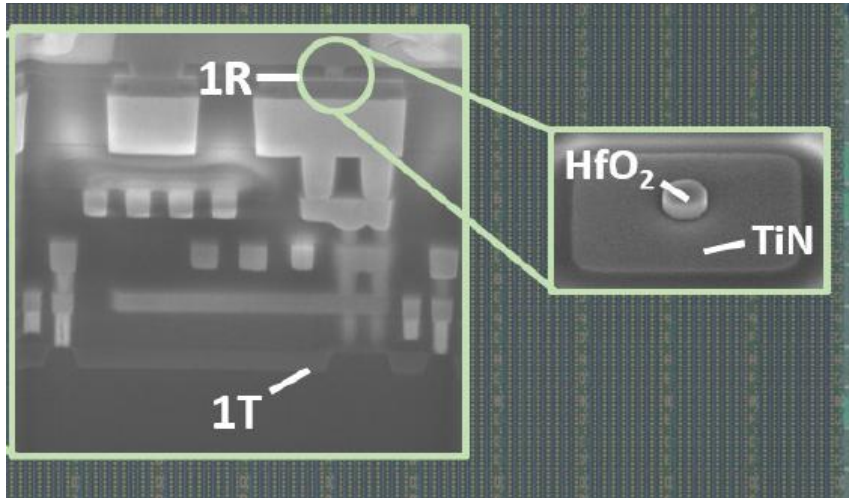


- The Analog & Stochastic Paths



- Learning with Physics

Memristor/RRAM: an Artificial Synapse!

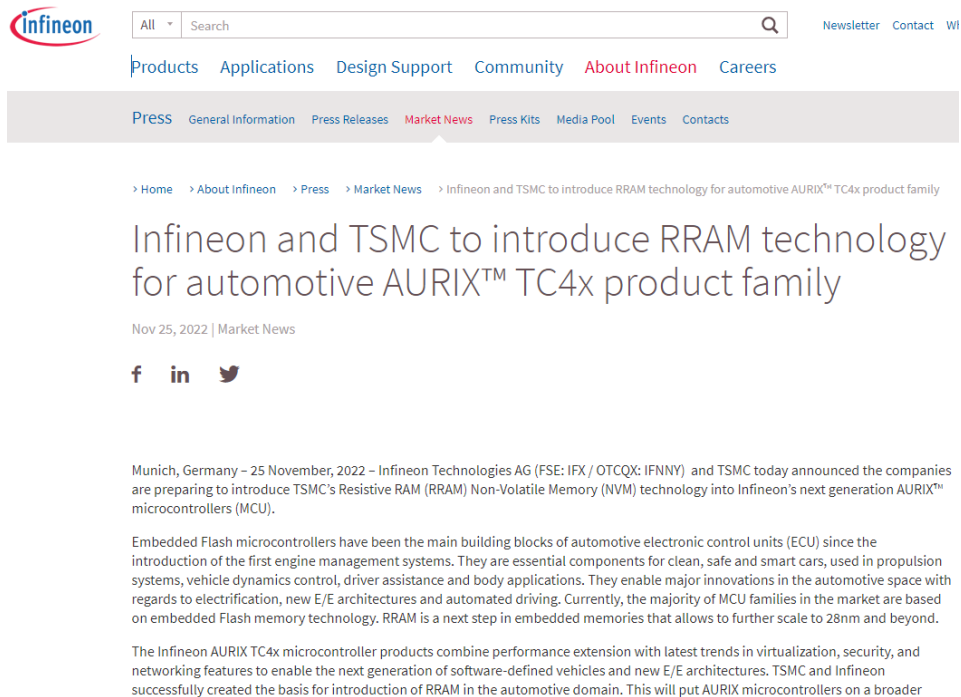


- TiN/HfO_x/Ti/TiN stack

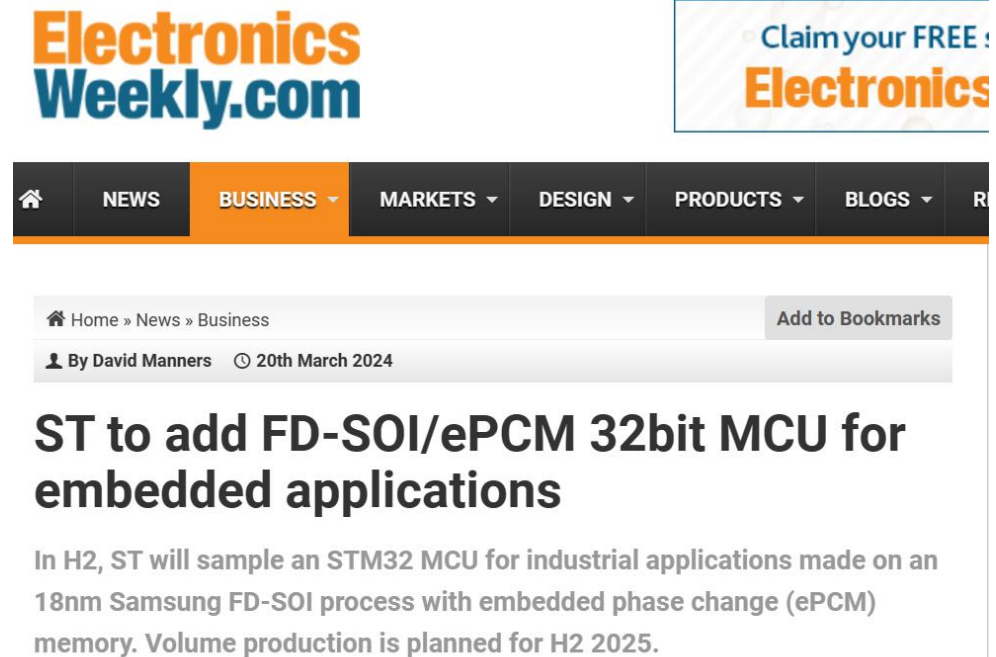
High voltage: move atoms to switch memristor between low/high resistance

Low voltage: allows reading the resistance

These New Memories Already Have a Market: Microcontroller Applications (NOR Flash replacement)



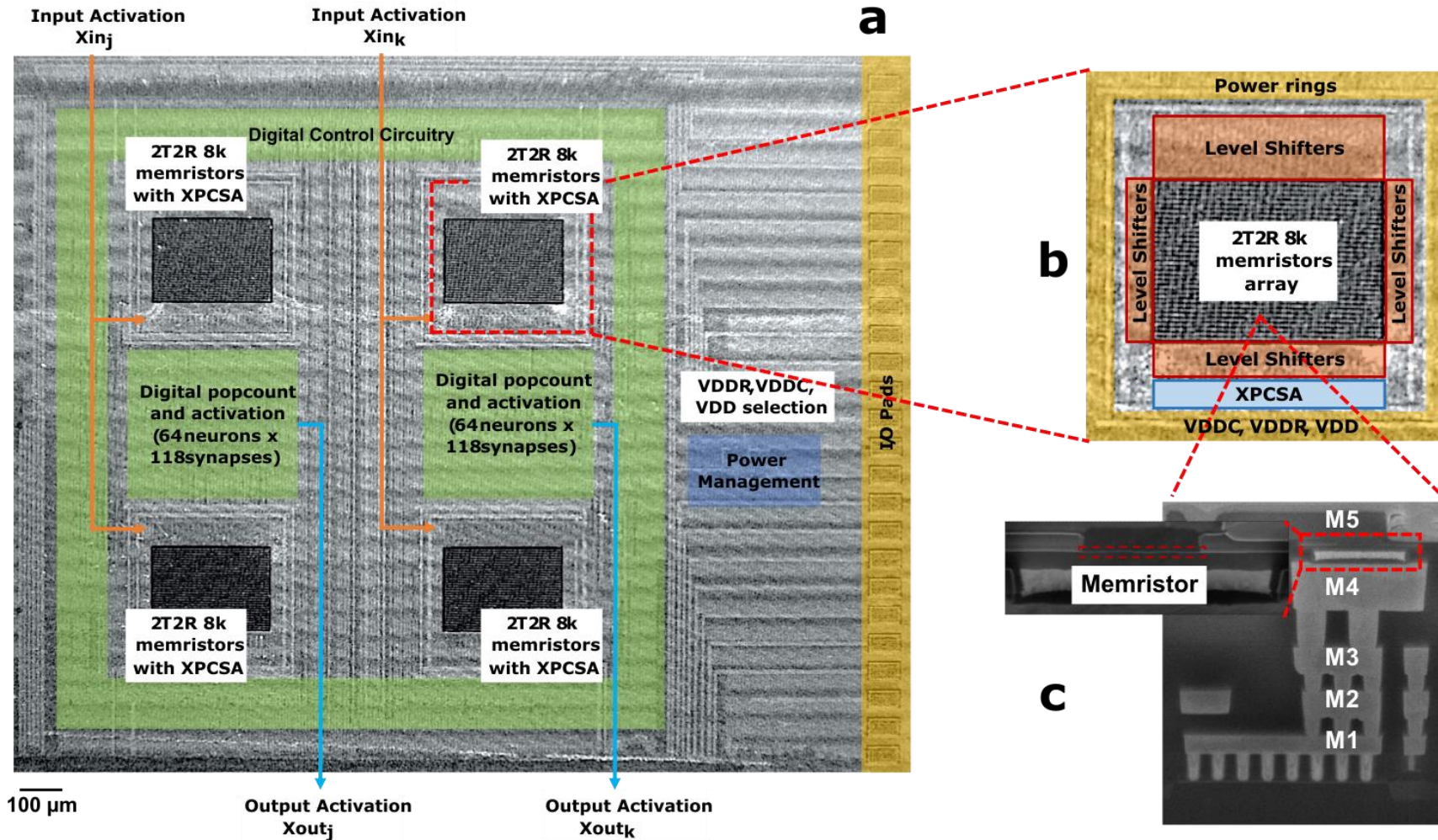
The screenshot shows the Infineon Technologies website. At the top is the Infineon logo and a search bar. Below the logo is a navigation menu with links: Products, Applications, Design Support, Community, About Infineon, and Careers. A secondary menu includes Press, General Information, Press Releases, Market News, Press Kits, Media Pool, Events, and Contacts. The main content area features a breadcrumb trail: > Home > About Infineon > Press > Market News > Infineon and TSMC to introduce RRAM technology for automotive AURIX™ TC4x product family. The headline reads: "Infineon and TSMC to introduce RRAM technology for automotive AURIX™ TC4x product family". Below the headline is the date "Nov 25, 2022 | Market News" and social media icons for Facebook, LinkedIn, and Twitter. The text of the article states: "Munich, Germany – 25 November, 2022 – Infineon Technologies AG (FSE: IFX / OTCQX: IFNNY) and TSMC today announced the companies are preparing to introduce TSMC's Resistive RAM (RRAM) Non-Volatile Memory (NVM) technology into Infineon's next generation AURIX™ microcontrollers (MCU). Embedded Flash microcontrollers have been the main building blocks of automotive electronic control units (ECU) since the introduction of the first engine management systems. They are essential components for clean, safe and smart cars, used in propulsion systems, vehicle dynamics control, driver assistance and body applications. They enable major innovations in the automotive space with regards to electrification, new E/E architectures and automated driving. Currently, the majority of MCU families in the market are based on embedded Flash memory technology. RRAM is a next step in embedded memories that allows to further scale to 28nm and beyond. The Infineon AURIX TC4x microcontroller products combine performance extension with latest trends in virtualization, security, and networking features to enable the next generation of software-defined vehicles and new E/E architectures. TSMC and Infineon successfully created the basis for introduction of RRAM in the automotive domain. This will put AURIX microcontrollers on a broader



The screenshot shows the Electronics Weekly.com website. At the top is the Electronics Weekly.com logo. To the right is a banner that says "Claim your FREE: Electronics". Below the logo is a navigation menu with links: Home, NEWS, BUSINESS, MARKETS, DESIGN, PRODUCTS, BLOGS, and R. The main content area features a breadcrumb trail: Home » News » Business. Below the breadcrumb trail is the author "By David Manners" and the date "20th March 2024". The headline reads: "ST to add FD-SOI/ePCM 32bit MCU for embedded applications". Below the headline is the text: "In H2, ST will sample an STM32 MCU for industrial applications made on an 18nm Samsung FD-SOI process with embedded phase change (ePCM) memory. Volume production is planned for H2 2025."

We repurpose them as *magic memory* for AI!

A Super-Robust Digital Binarized Neural Network

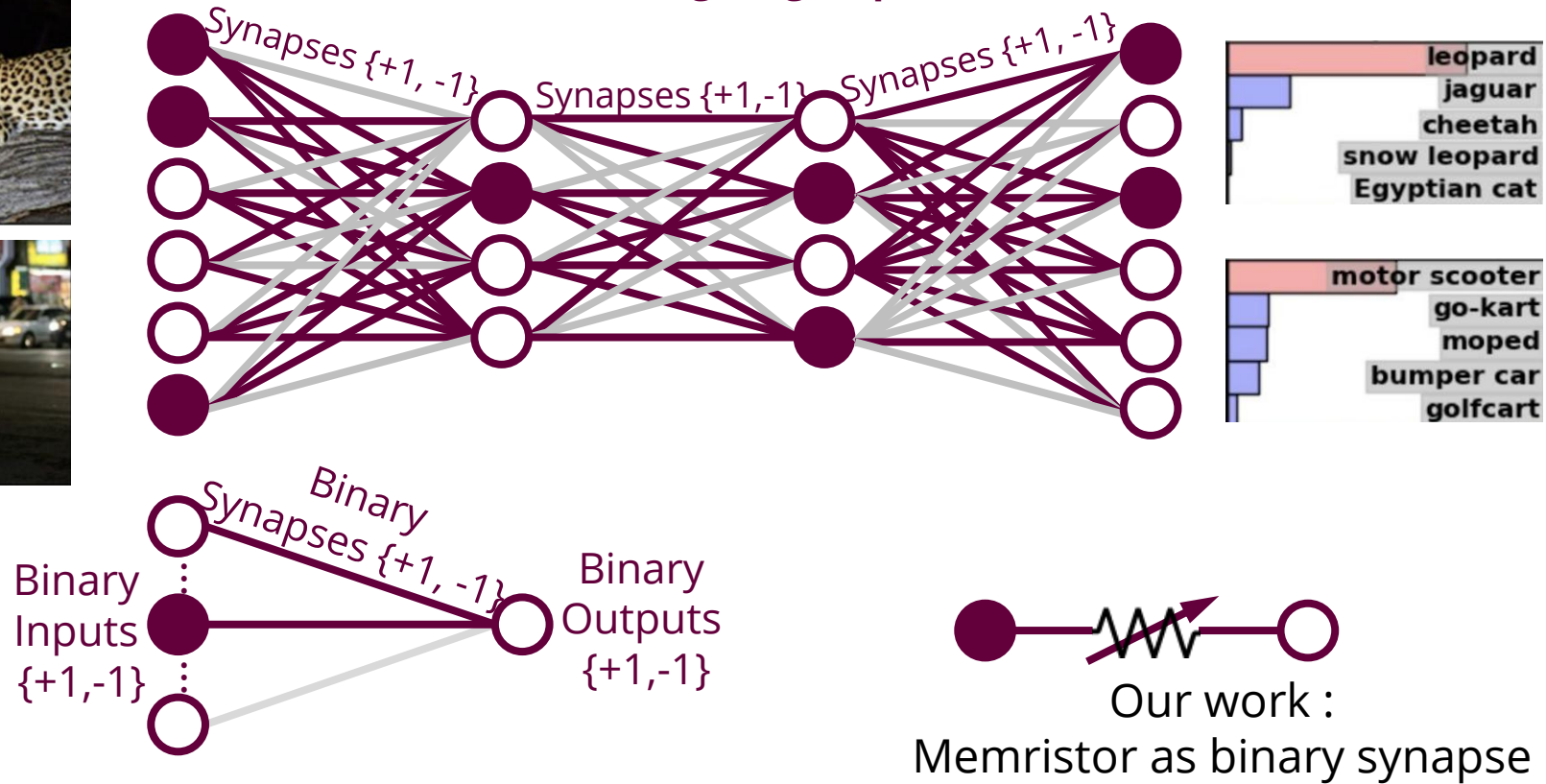


Collaboration

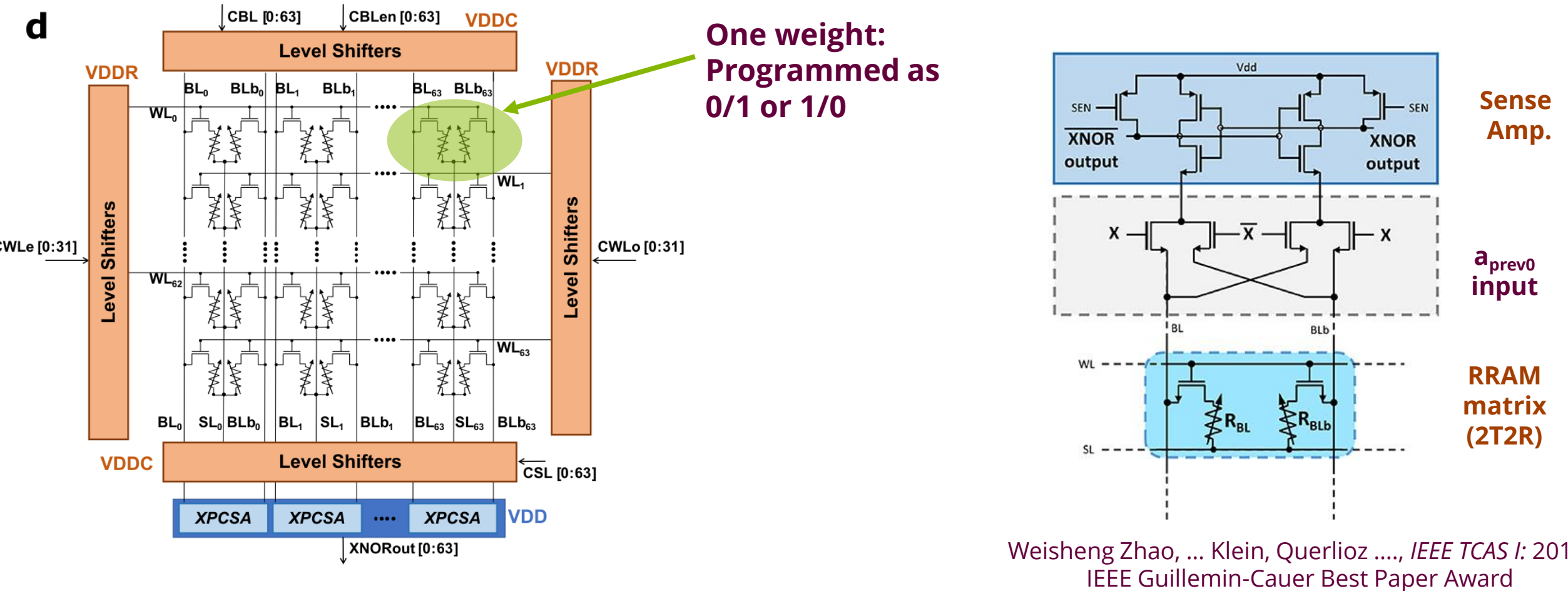


Binarized Neural network: A Low Precision Neural Networks

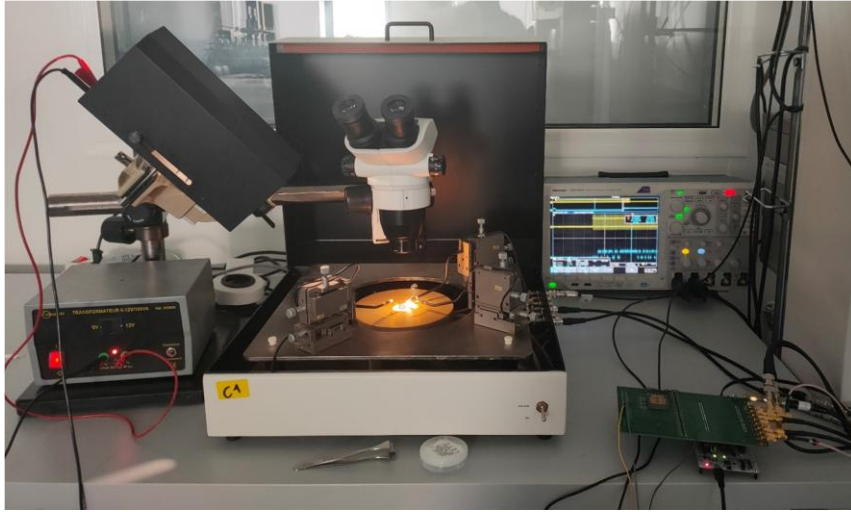
Hubara, Courbariaux et al. NIPS 2016
Yoshua Bengio's group



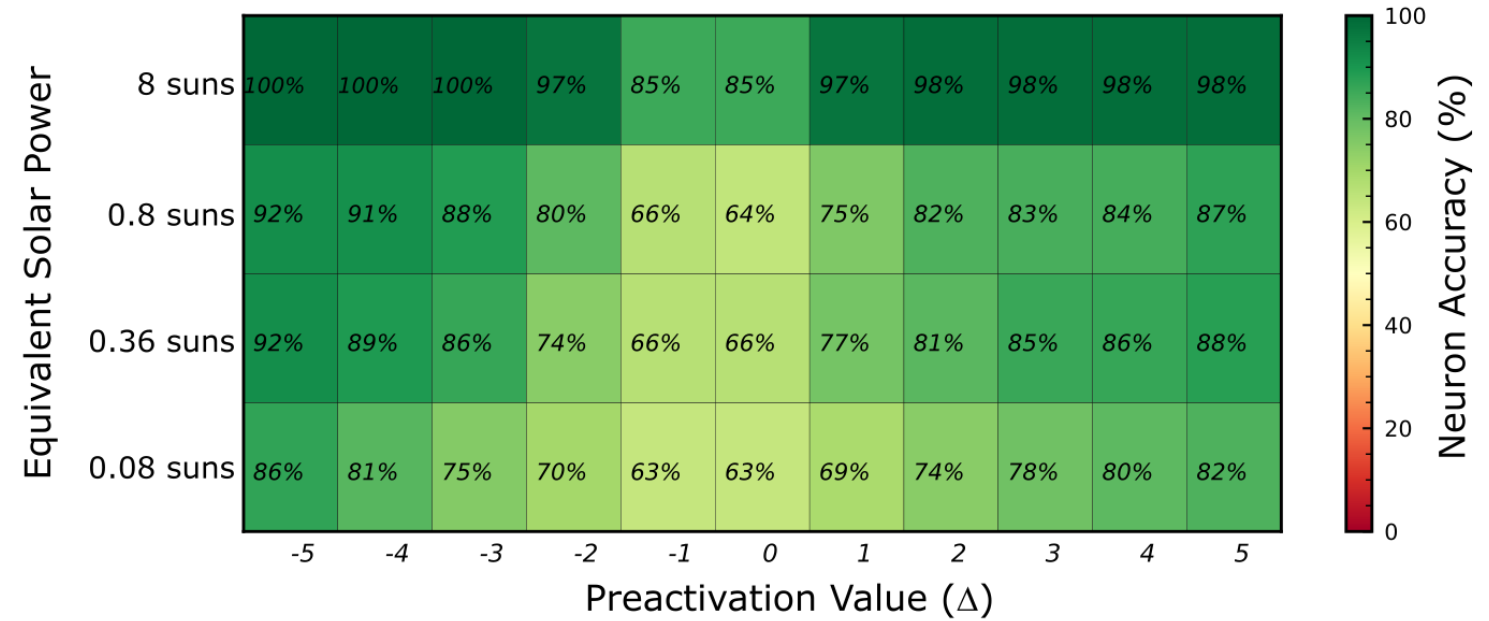
Robust Logic-In-Memory Feature: Multiplication Within the Sense Amplifier



Self-Powered Operation



Miniature wide-bandgap solar cell



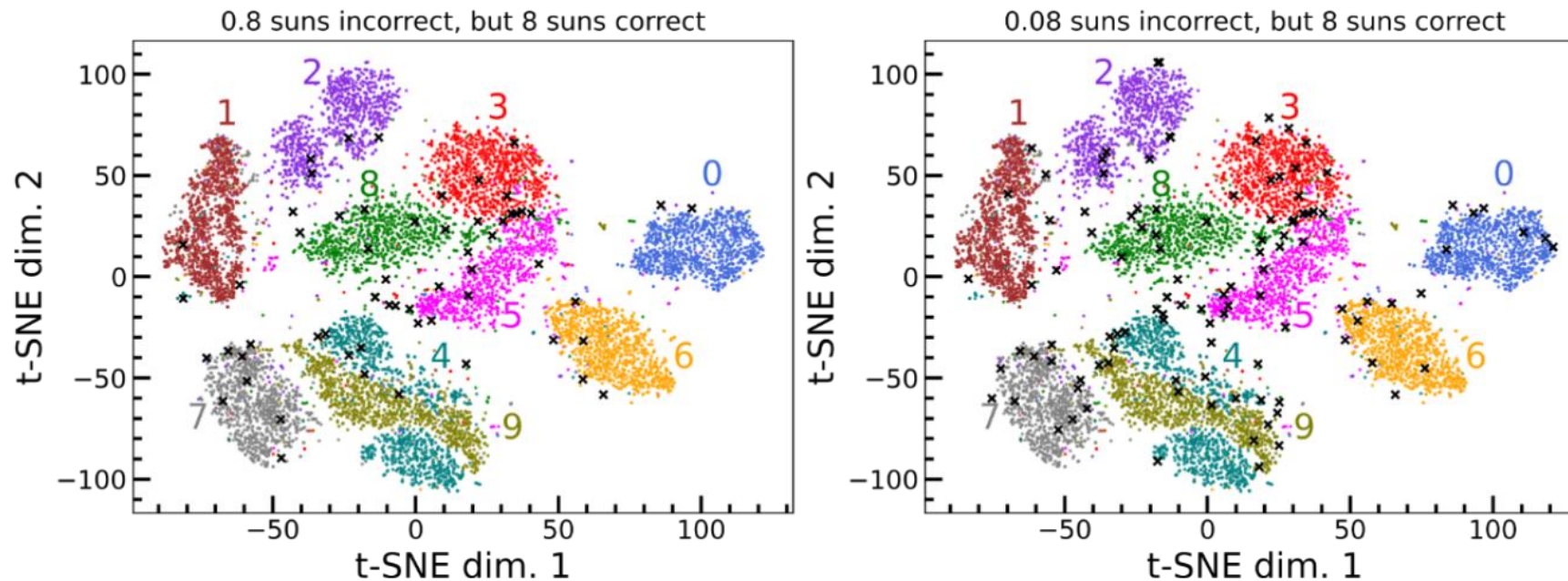
Neuron value $t_j = f(\sum w_{ij}s_i)$

Under low illumination the circuit naturally switches to approximate computation

Self-Powered Operation

0 1 2 3 4 5 6 7 8 9

Illumination	8 suns	0.8 suns	0.08 suns
Accuracy	97.2%	96.9%	96.5%



Computing In-Near Memory Is Applicable to Other AI Approaches



Thomas Bayes

Likelihoods

Prior

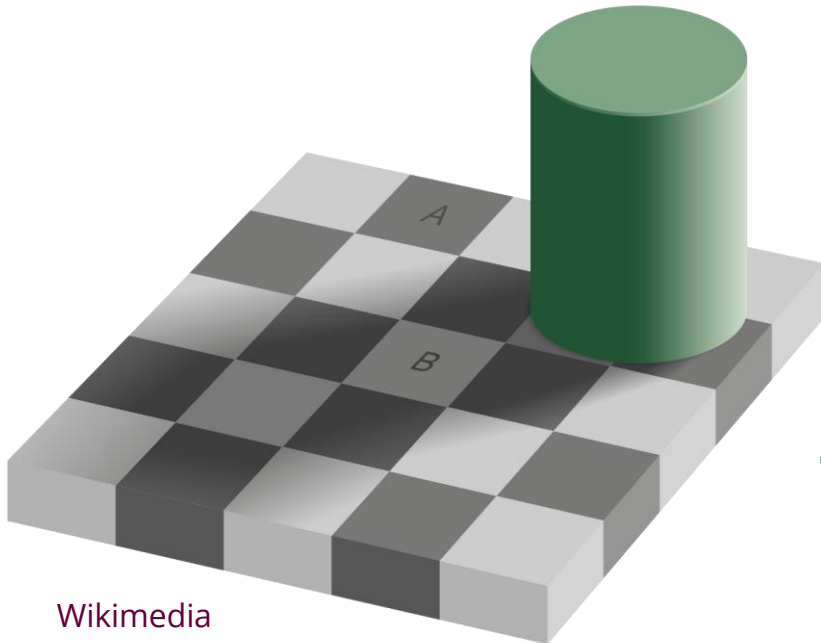
$$p(\text{Disease} \mid \text{Observations}) \propto p(\text{Observations} \mid \text{Disease}) \times p(\text{Disease})$$



Constructed with expert knowledge+Data

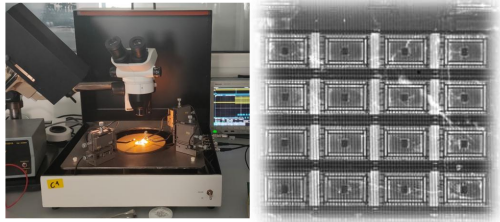
Hard to Compute

The Brain Might Be Using Bayesian Reasoning

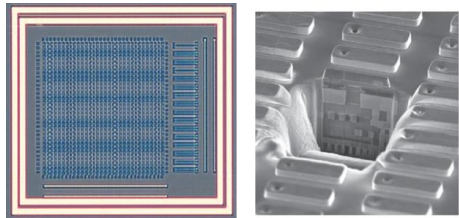


Wikimedia

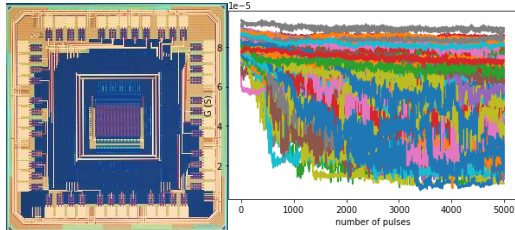
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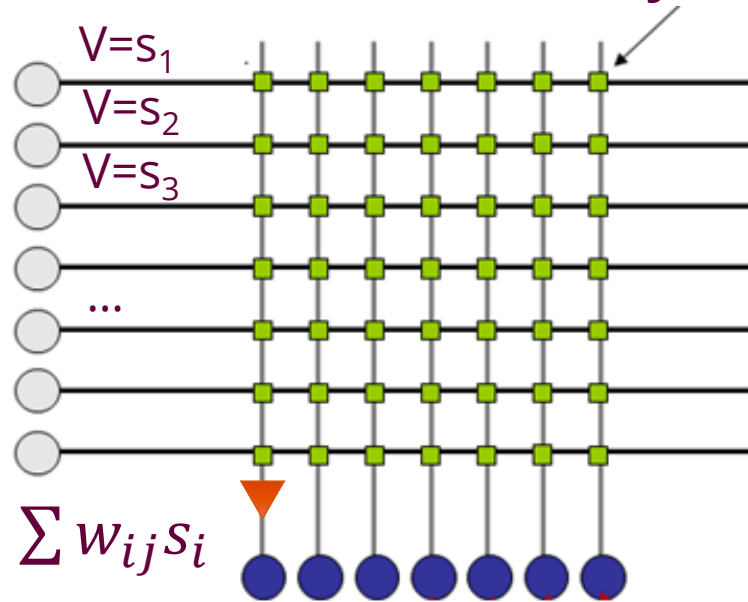


- Learning with Physics

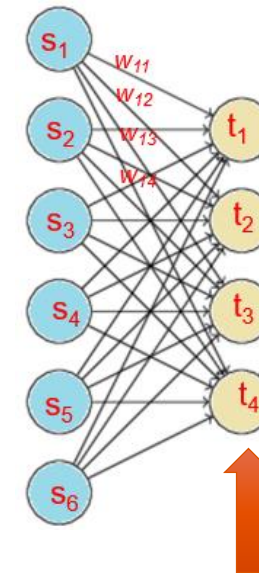
Analog In-Memory Computing Performs Neural Network Inference Very Naturally

A matrix of analog memristors naturally implements a layer of neural network with **Ohm's and Kirchhoff's laws!**

Memristor conductance G = synaptic weight w

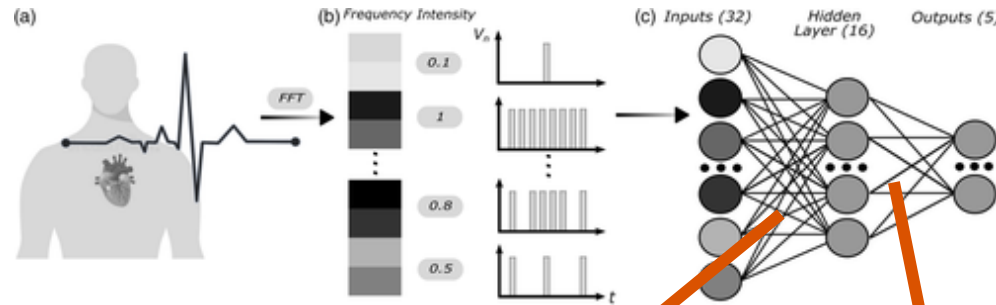


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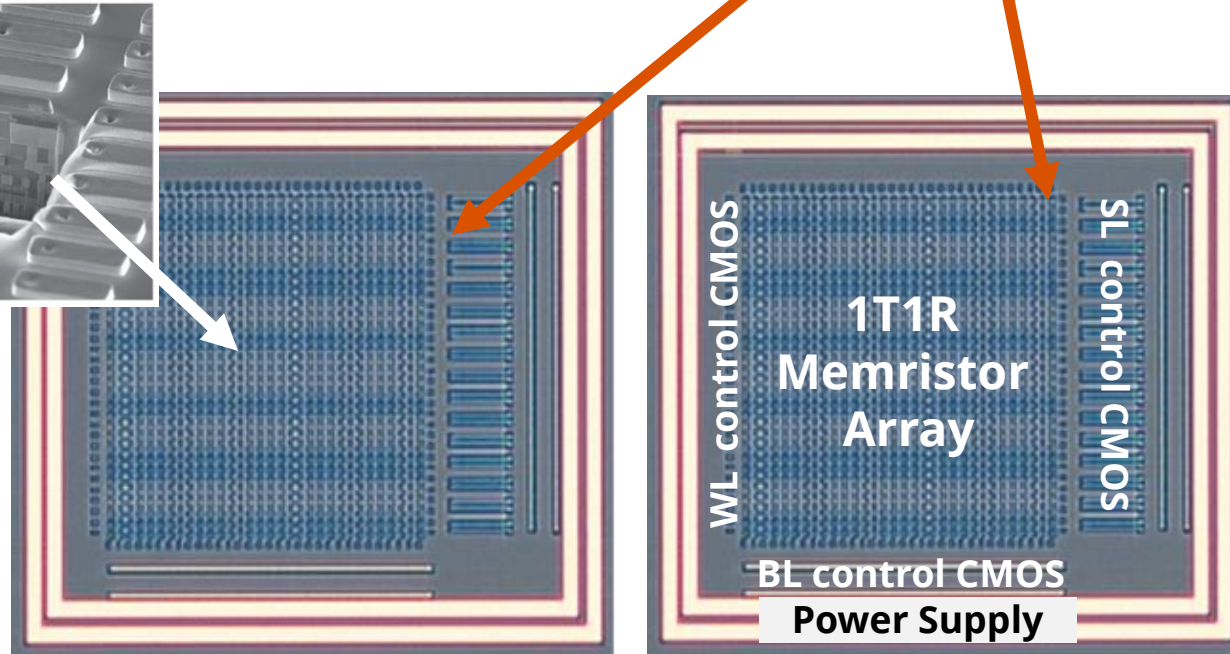
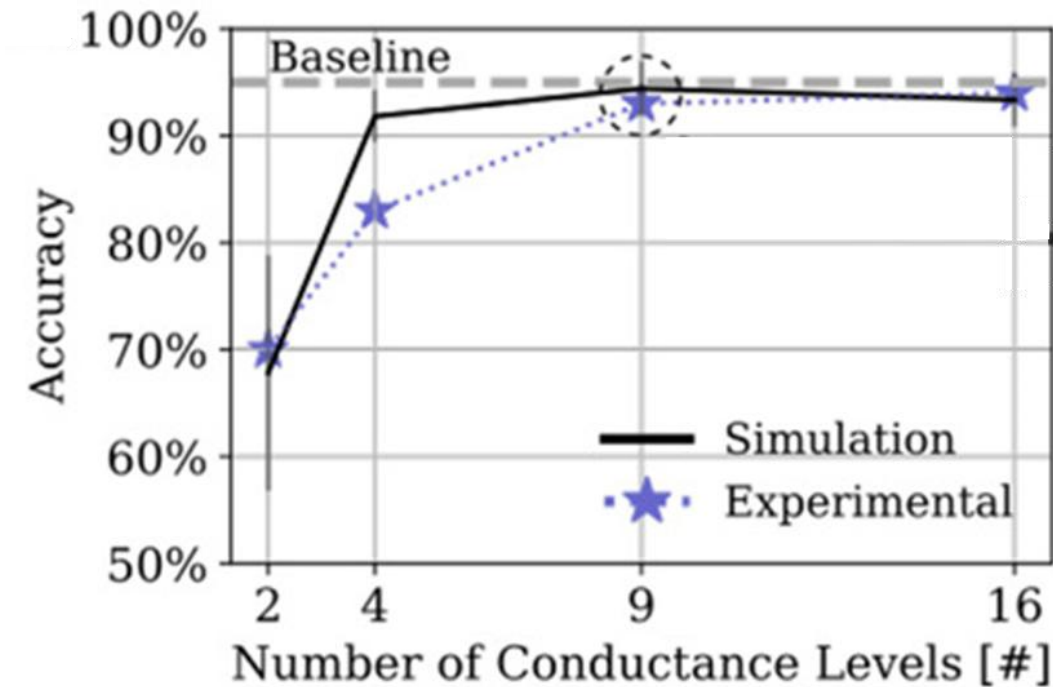


Neuron value
 $t_j = f(\sum w_{ij}s_i)$

Analog In-Memory Computing with Memristors



Accuracy on arrhythmia identification



HfO_x memristor integrated in BEOL of 130 nm-CMOS

Esmanhotto et al, 2200145, Advanced Intelligent Systems, 2022

Collaboration



16



Current State of the Art (IBM Research, Almaden)

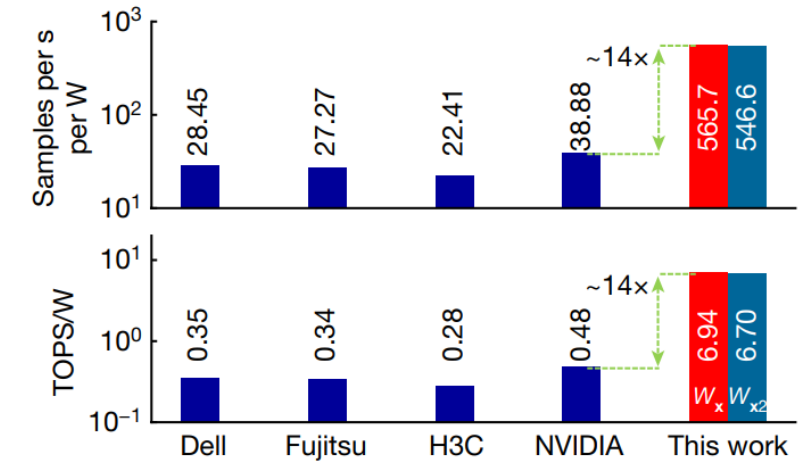
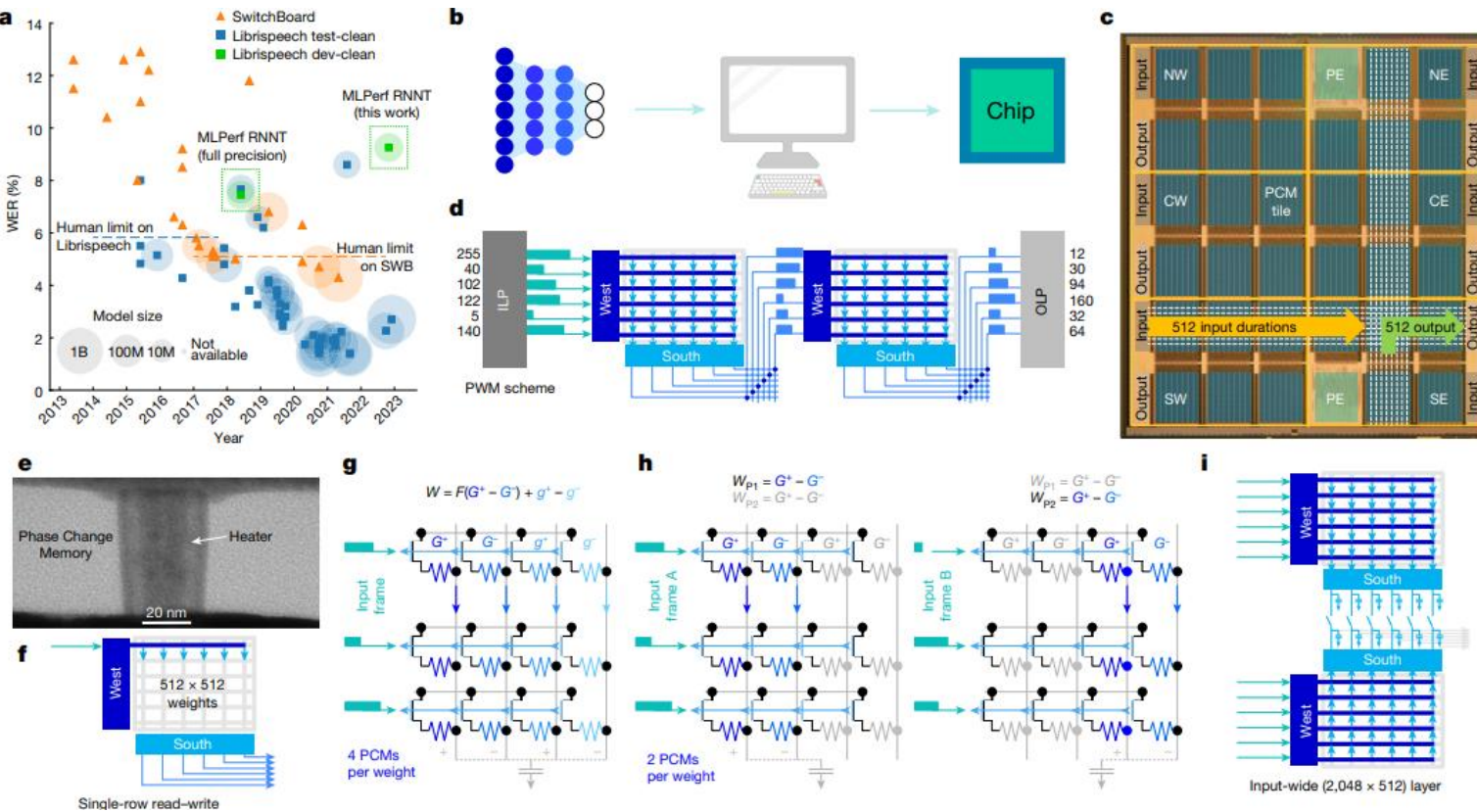
Article

An analog-AI chip for energy-efficient speech recognition and transcription

<https://doi.org/10.1038/s41586-023-06337-5>

Received: 13 December 2022

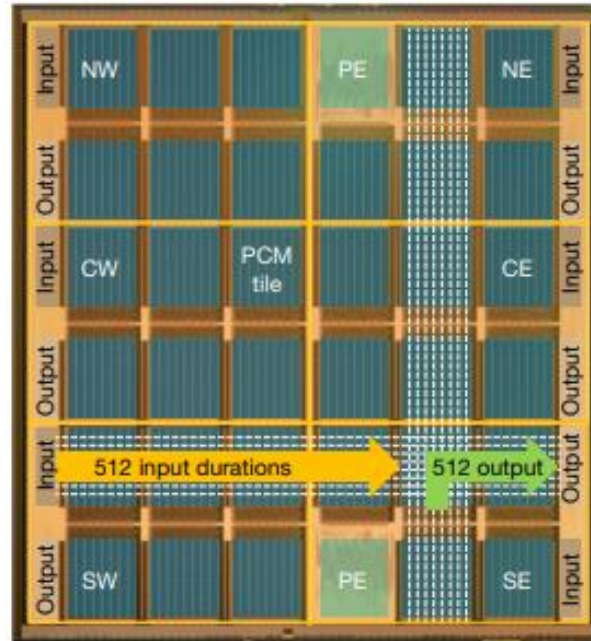
S. Ambrogio^{1,✉}, P. Narayanan¹, A. Okazaki², A. Fasoli¹, C. Mackin¹, K. Hosokawa², A. Nomura², T. Yasuda², A. Chen¹, A. Friz¹, M. Ishii², J. Luquin¹, Y. Kohda², N. Saulnier³, K. Brew³, S. Choi³, I. Ok³, T. Philip³, V. Chan³, C. Silvestre³, I. Ahsan³, V. Narayanan⁴, H. Tsai¹ & G. W. Burr¹



Despite prototype nature, 14x more energy efficient than any AI accelerator

- 35M phase change memories

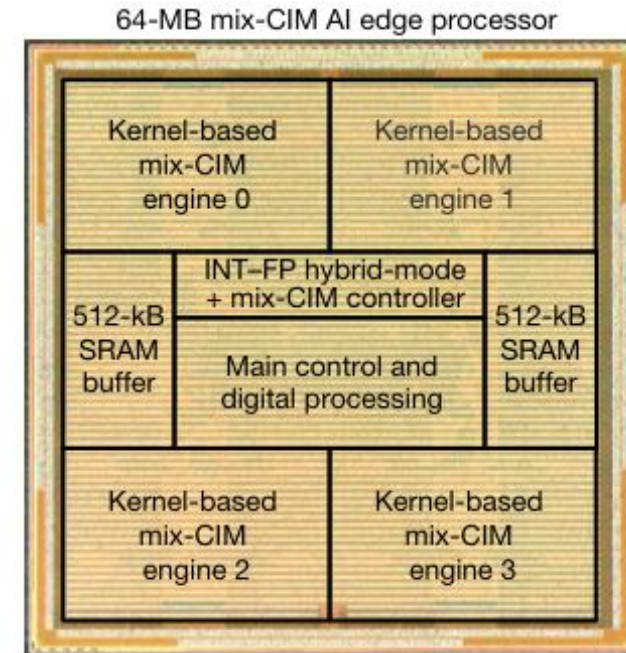
Current State of the Art



IBM Research

LSTM Language model
35M memristors (phase change)
Ambrogio et al, Nature 2023

7 TOPS/W
(140 fj/operation)



TSMC Research/NTHU

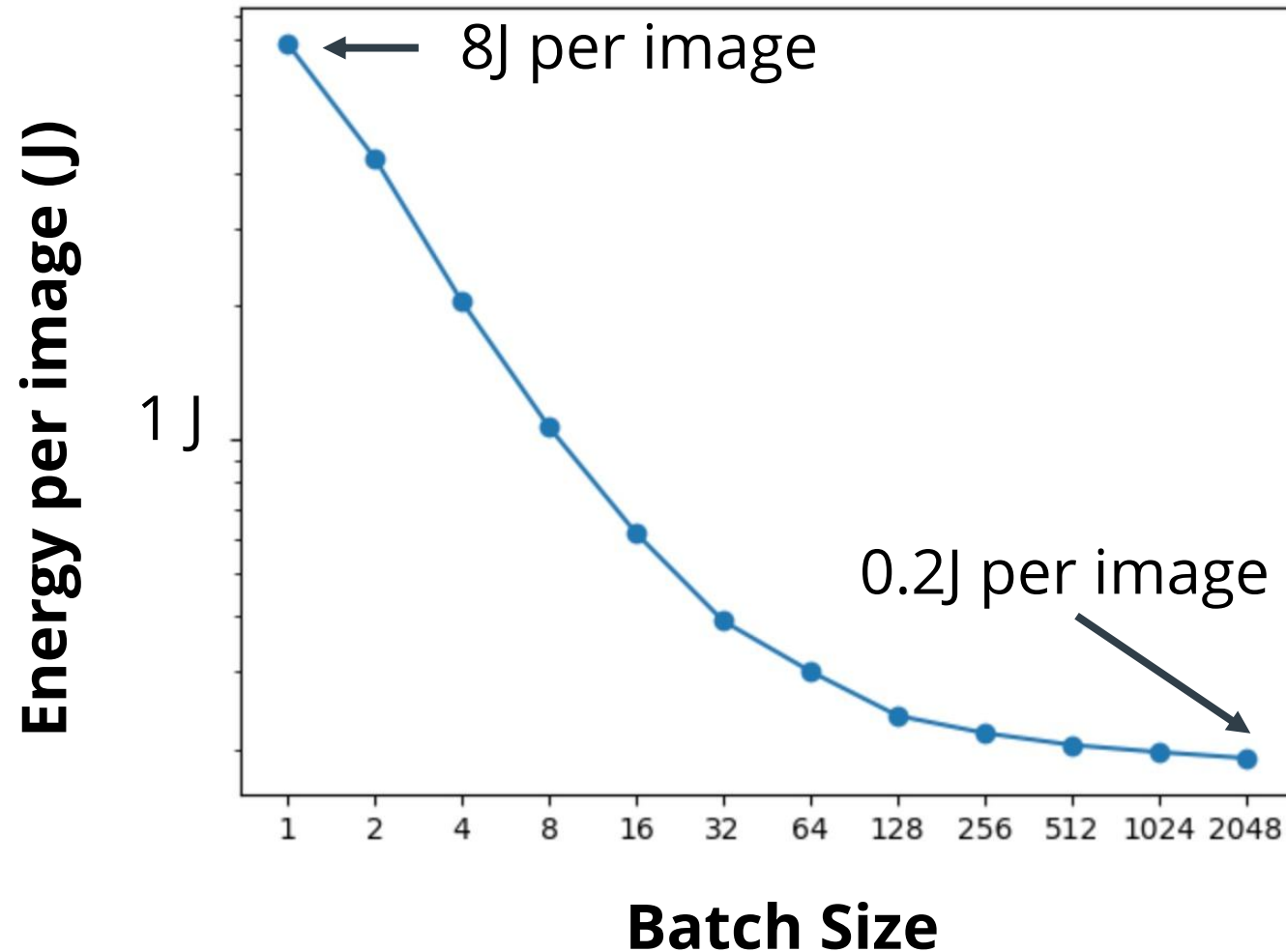
MobileNet-v2
64M memristors
Khwa et al, Nature 2025

40 TOPS/W
(25 fj/operation)

« These TOPS/W Are Not That High »

- Only prototypes
- **TOPS/W is a problem metric**

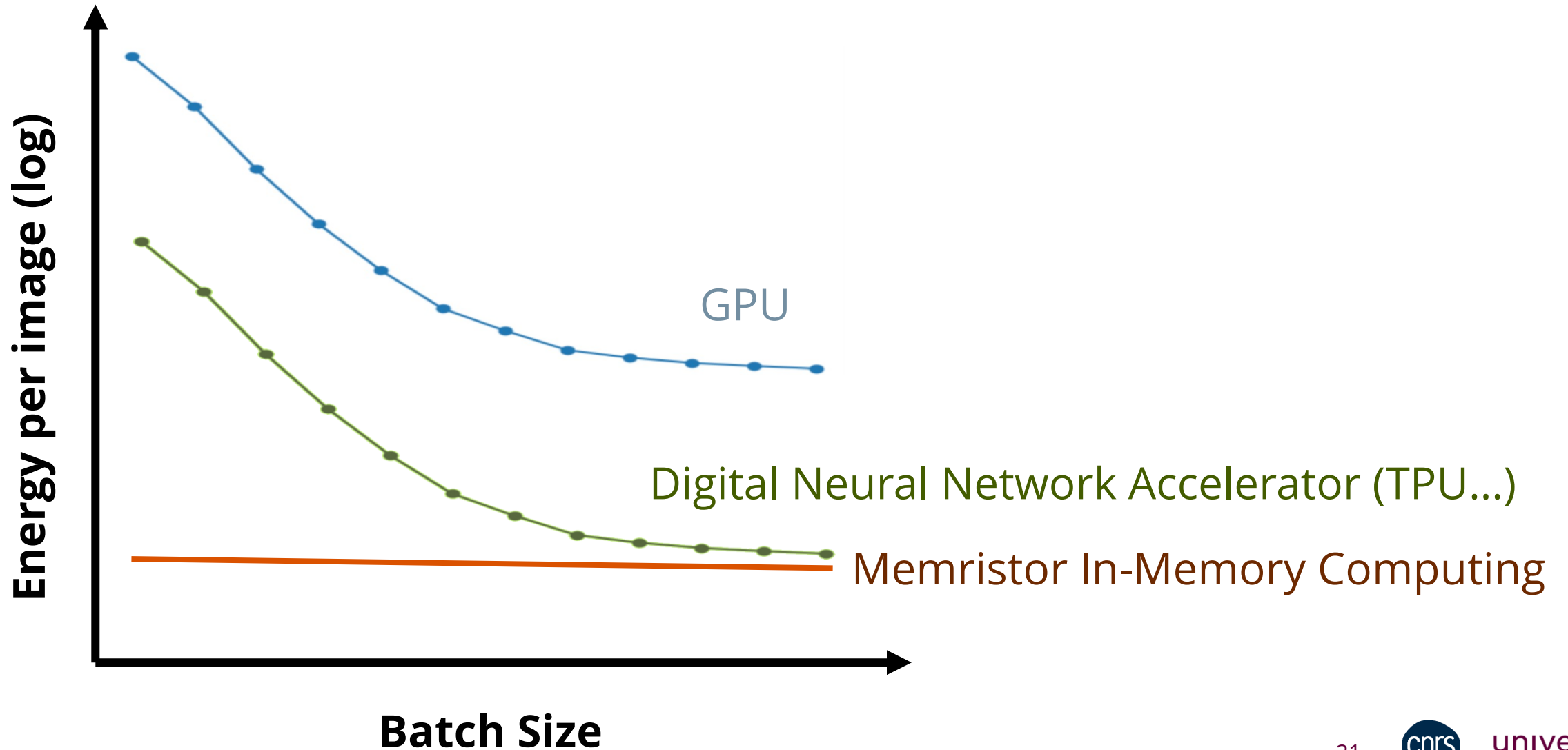
Real Energy Consumption Can Be Dramatically Higher than Peak



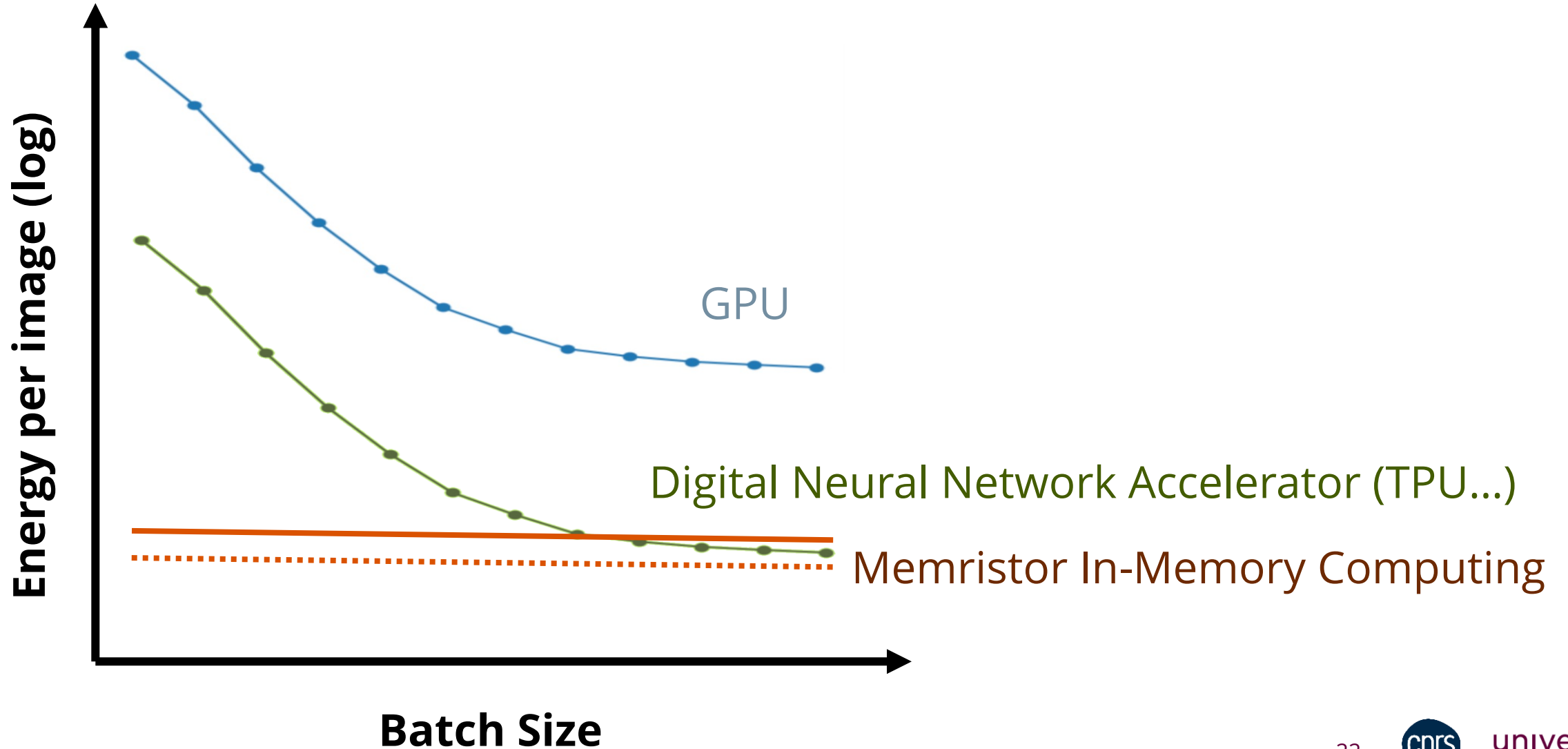
NVIDIA A100 GPU
ResNet50

*Courtesy of David Novo
(Univ Montpellier/CNRS)*

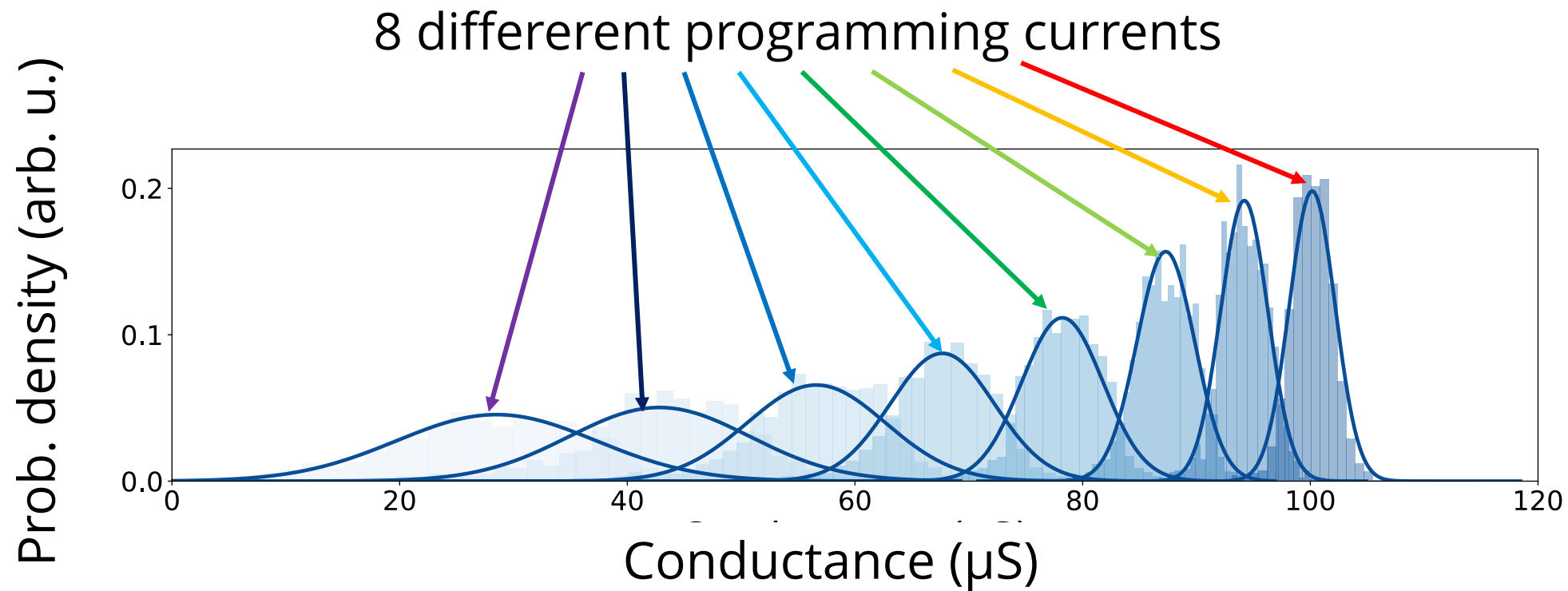
What Memristors Can Do



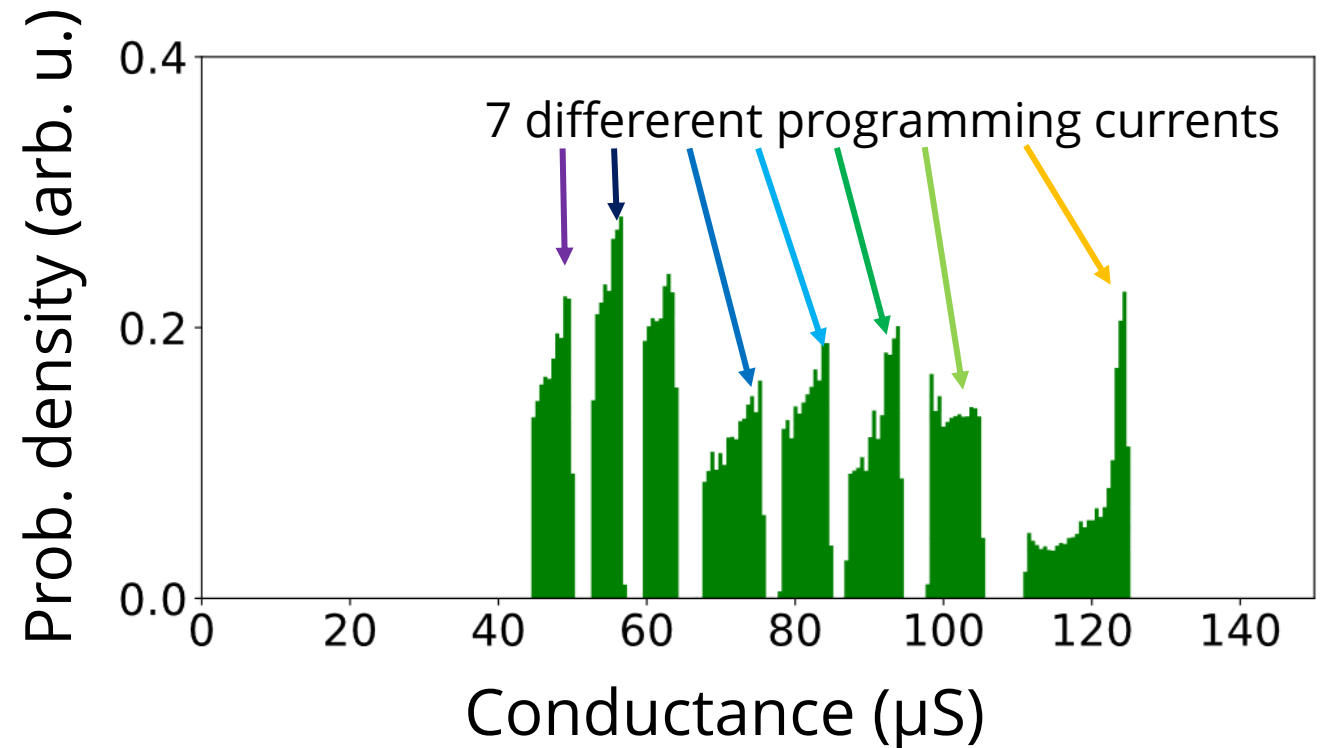
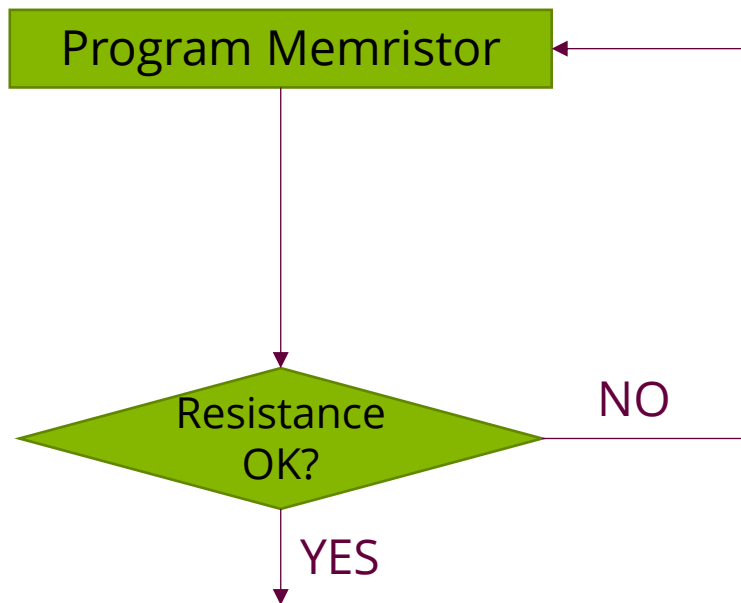
What Memristors Can Do



The Challenge of Analog In-Memory Computing: Memristors Act as Random Variables

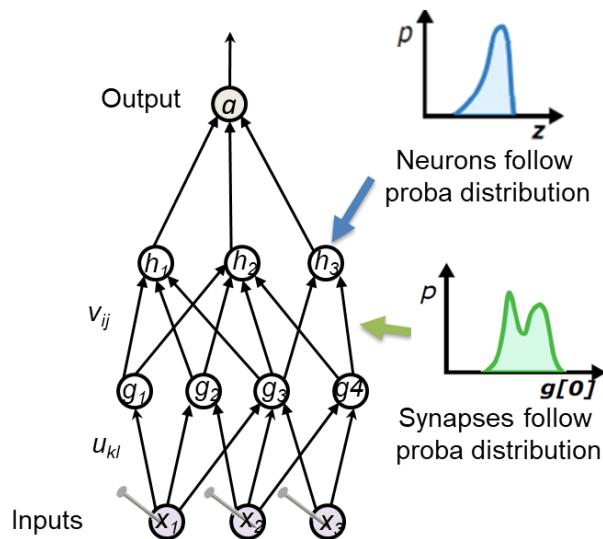


Fighting the Random Character of Memristors: *Program and Verify*

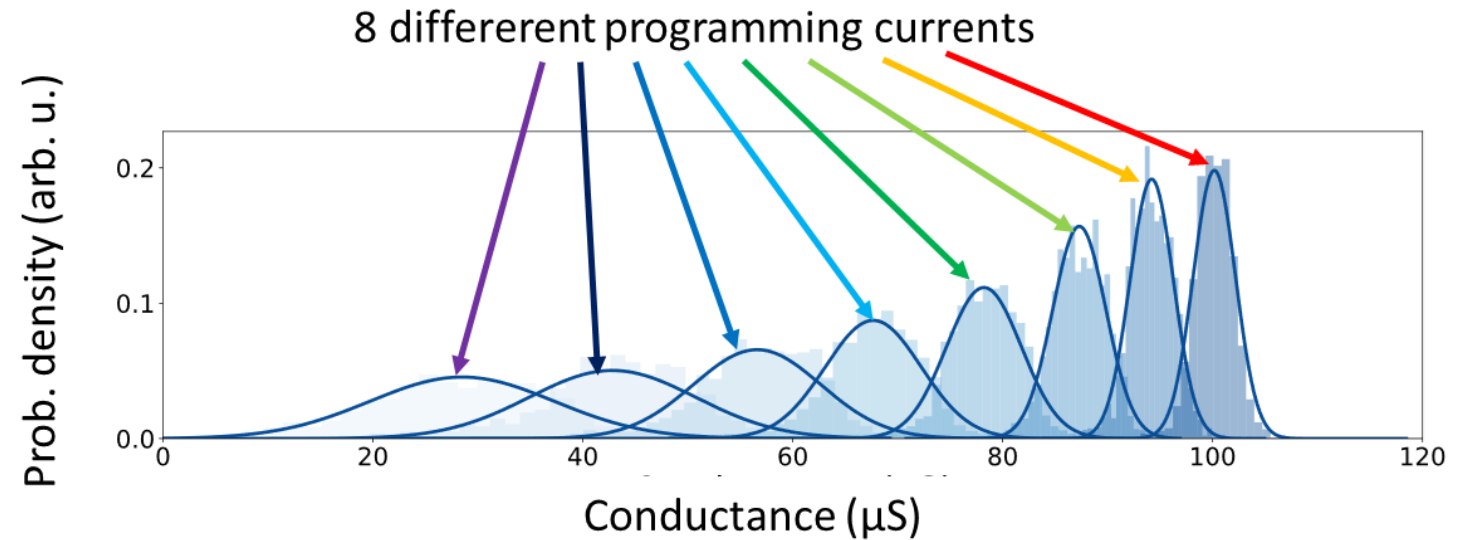


Memristor Imperfections Can Naturally Produce a *Bayesian* Neural Network!

In Bayesian models, everything is a random variable that follows specific probability distributions



Memristors actually act as a random variable that follow specific probability distributions!



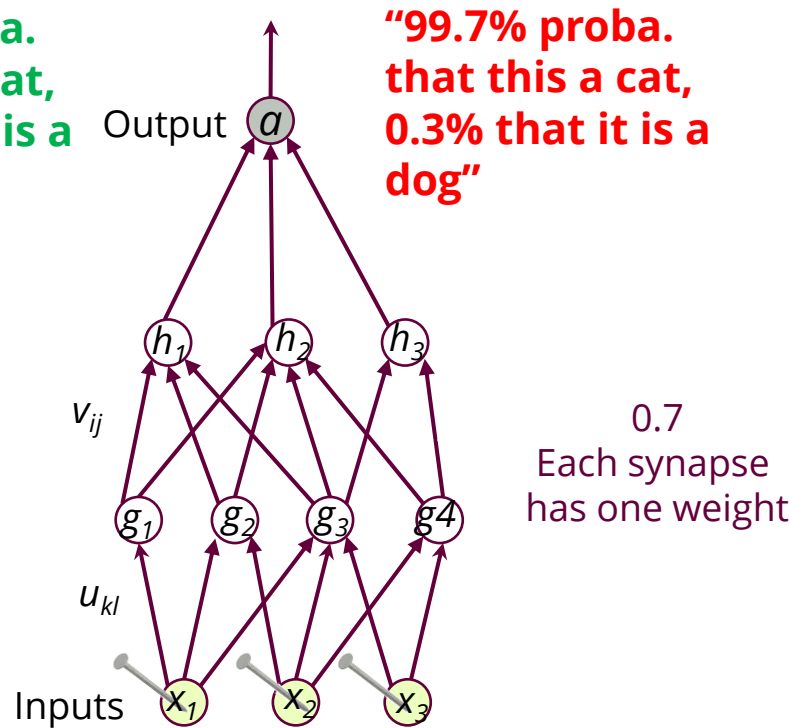
Our concept: Bayesian models can be a “better” way to exploit memristors

Bayesian Neural Networks

Assuming NN was trained to recognize « cats » and « dogs »

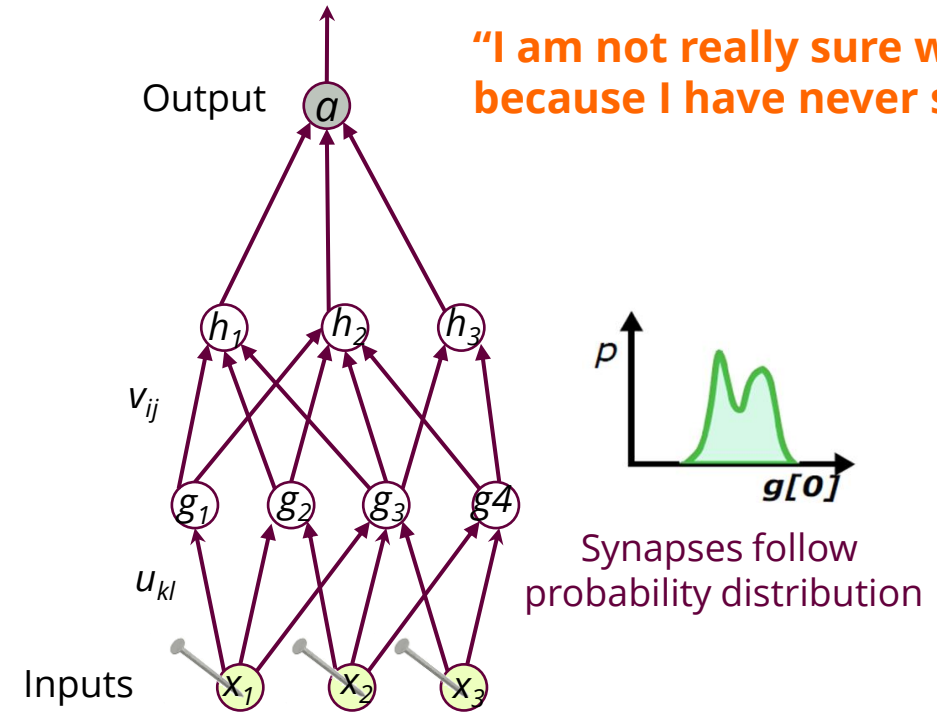
Conventional Neural Network

“99.9% proba.
that this a cat,
0.1% that it is a
dog”



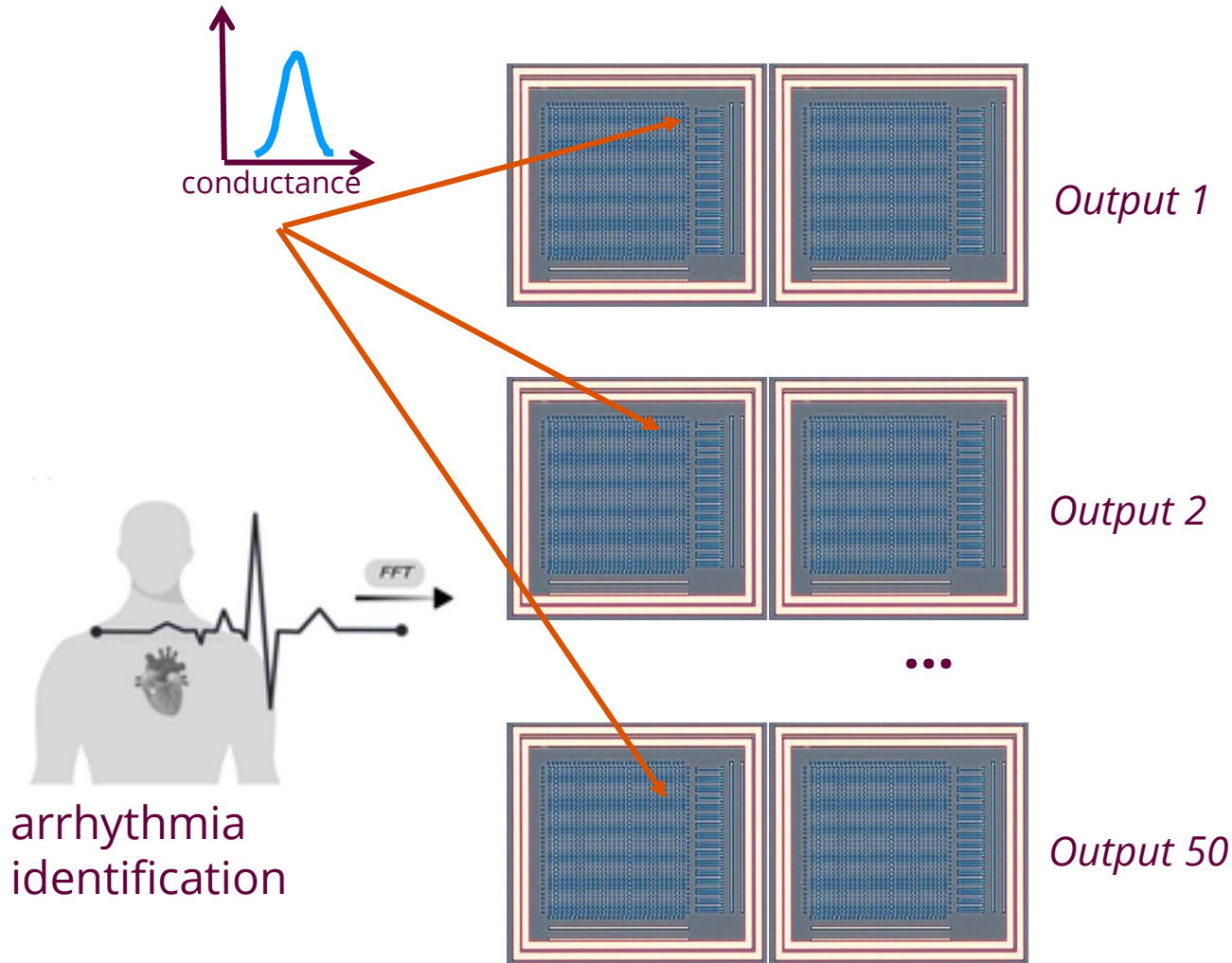
Bayesian Neural Network

“I am not really sure what this is,
because I have never seen it”



Memristor-Based Bayesian Neural Networks

We program 50 memristor-neural networks (each with two layers). We apply same input to them

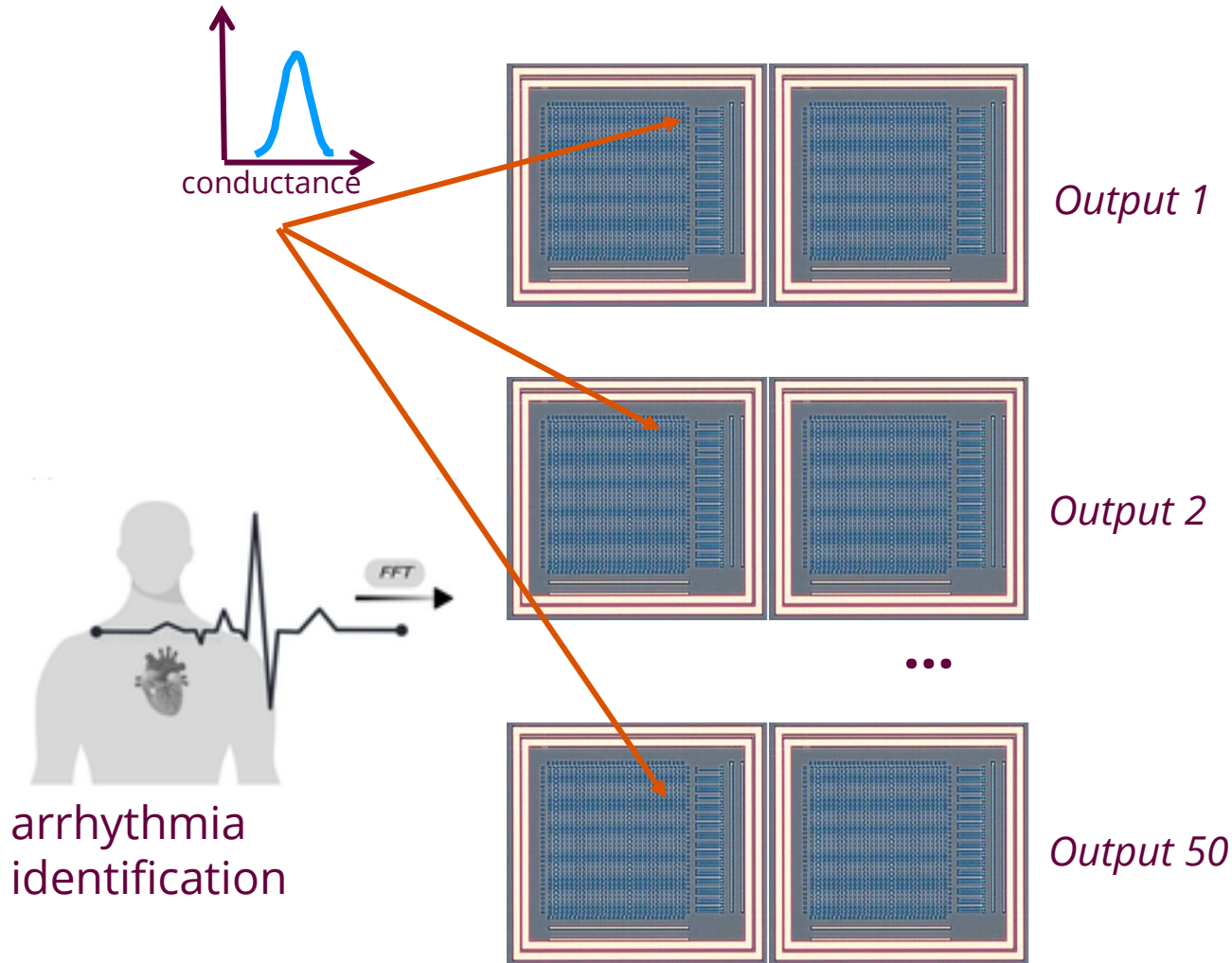


We get 50 outputs:
their dispersion tells about
the *certainty* of the neural
network

**Neural network trained
with a “technological
loss”**

Memristor-Based Bayesian Neural Networks

We program 50 memristor-neural networks (each with two layers). We apply same input to them

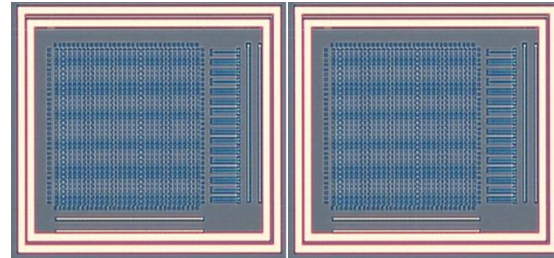


We get 50 outputs:
their dispersion tells about
the *certainty* of the neural
network

**Neural network trained
with Variational
Inference incorporating a
specific “technological
loss”**

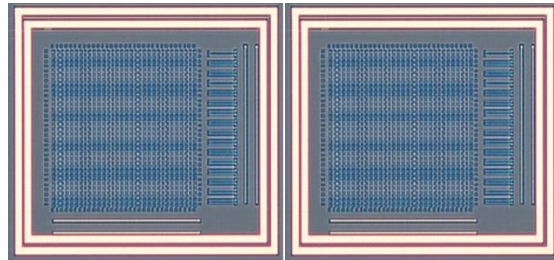
Memristor-Based Bayesian Neural Networks

We program 50 memristor-neural networks. We apply same input to them



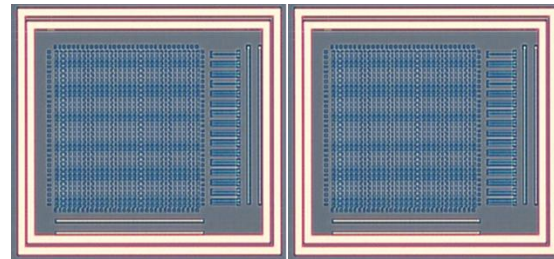
Arrhythmia type 1

LOW UNCERTAINTY

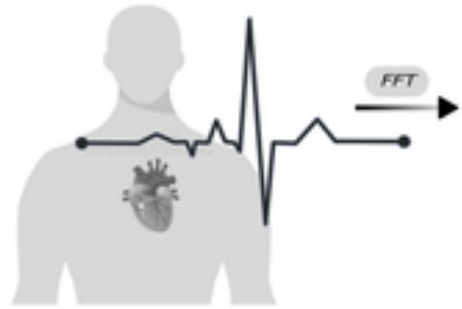


Arrhythmia type 1

...



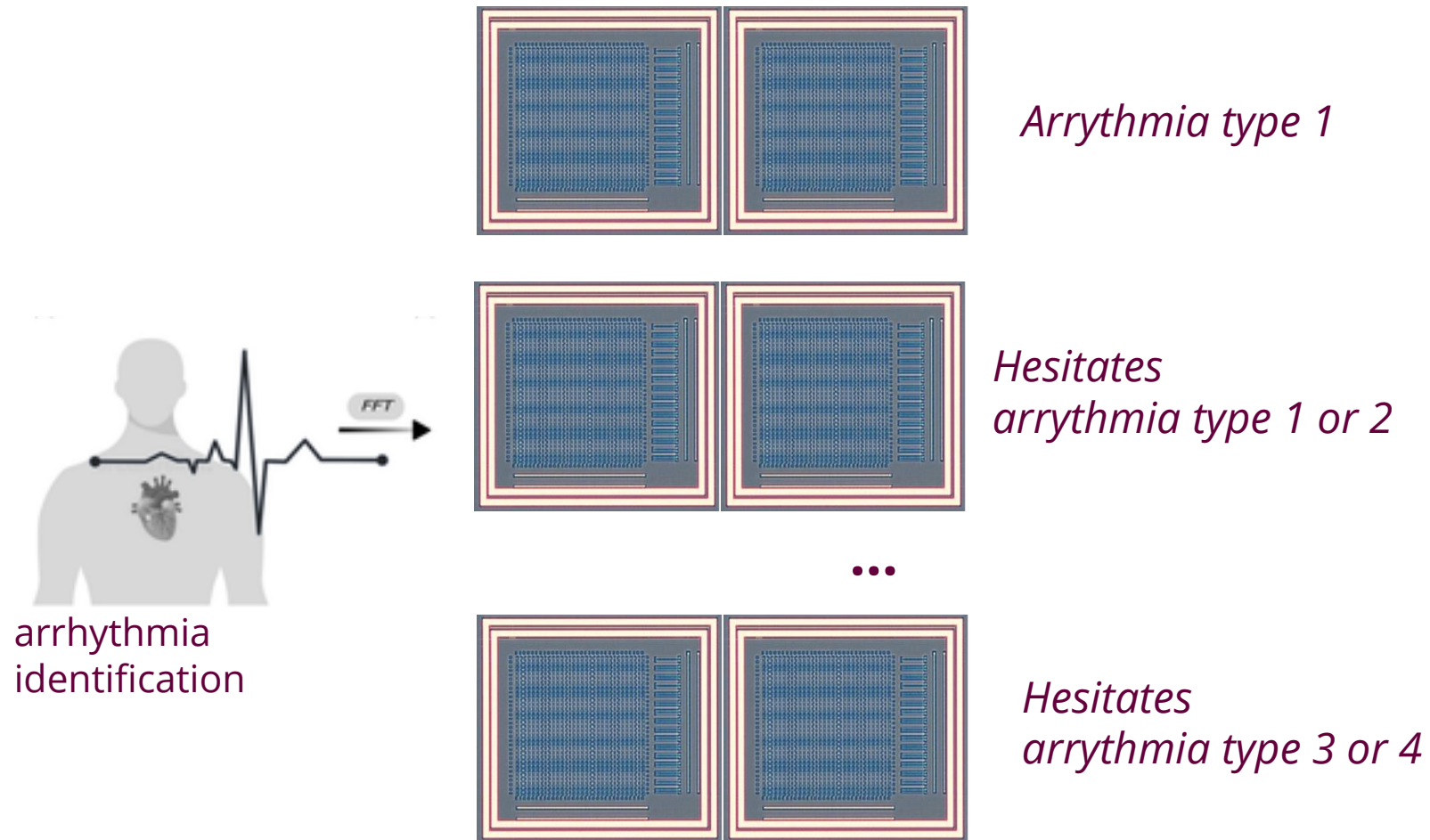
Arrhythmia type 1



arrhythmia
identification

Memristor-Based Bayesian Neural Networks

We program 50 memristor arrays, and we apply the same input to them



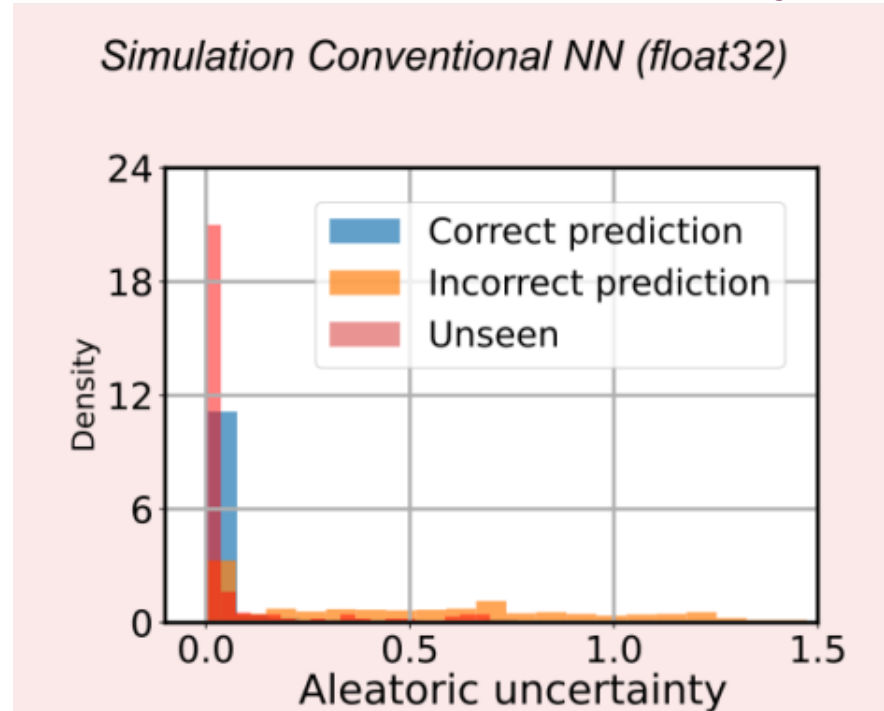
Unknown data:

**EPISTEMIC
UNCERTAINTY**

Fully Experimental Arrhythmia Recognition

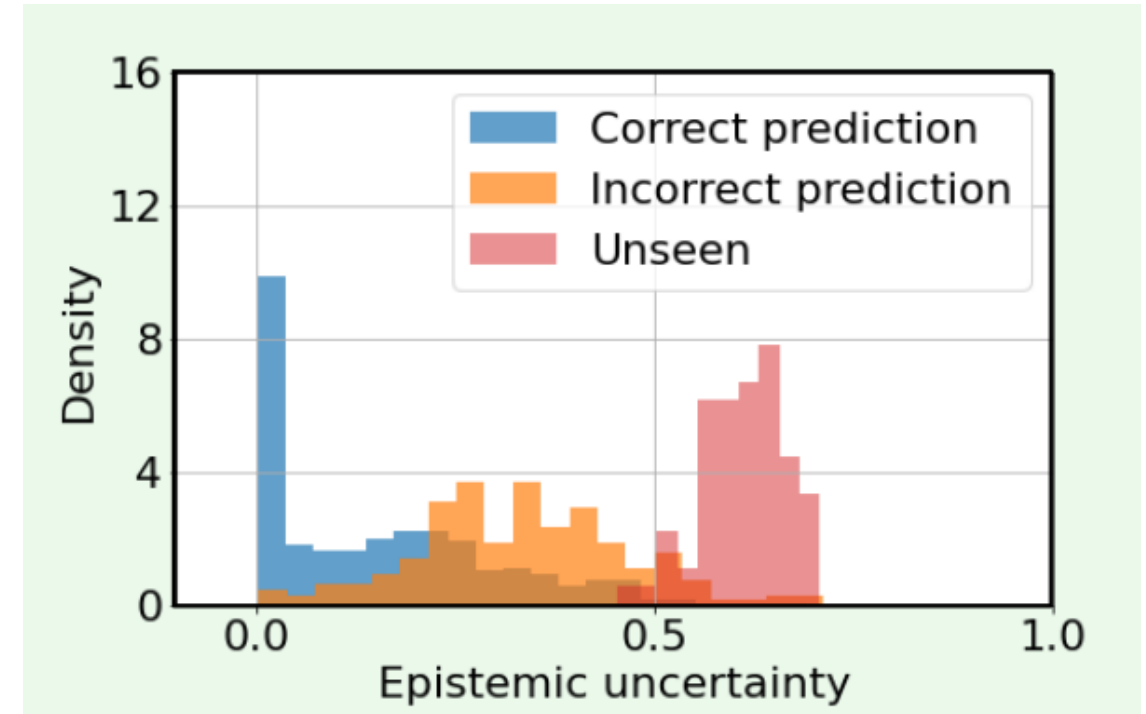
Traditional Neural Network

80% classification accuracy



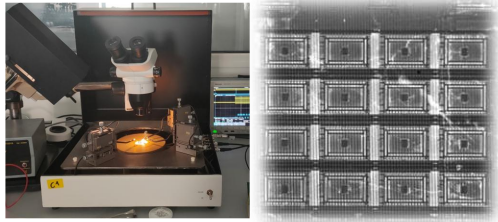
Bayesian Neural Network

79% classification accuracy

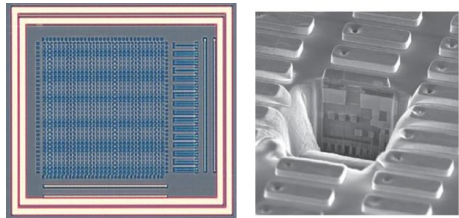


Easily recognizes
unknown types of arrhythmia

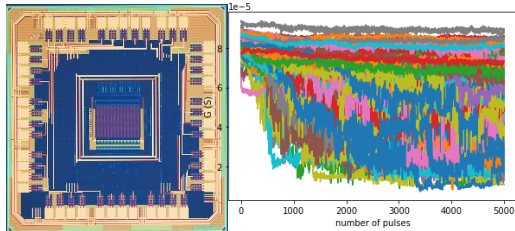
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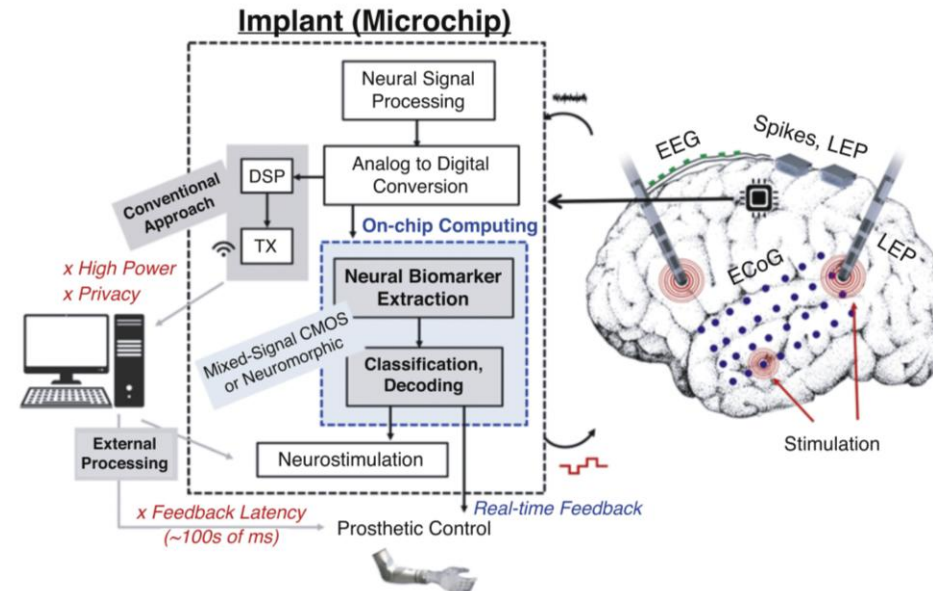


- Learning with Physics

The Grand Challenge of On-Chip Learning

- Current in-memory computing AI accelerators are focused on inference
- On-chip learning/adaptation would also have tremendous prospects

Medical applications

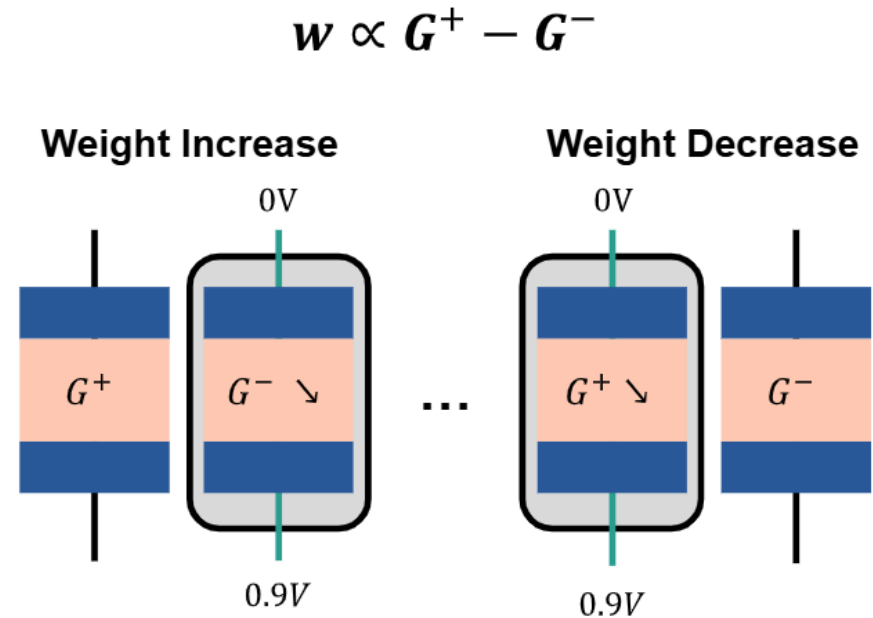
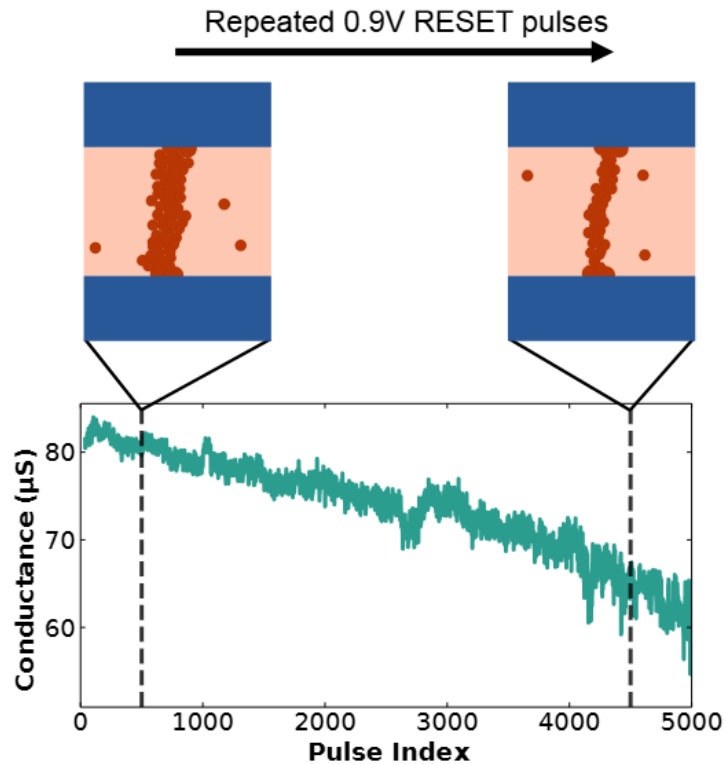


Yoo and Shoaran,
Current Opinion Biotechnol., 2021

Current Opinion in Biotechnology

But on-Chip learning requires reprogramming the weights repeatedly

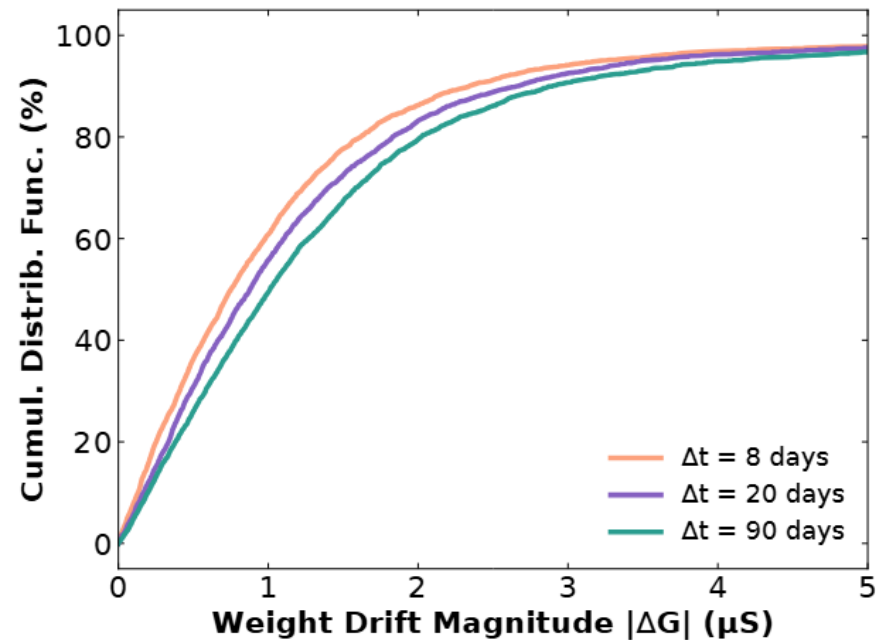
Learning With Memristor Low-Voltage Reset



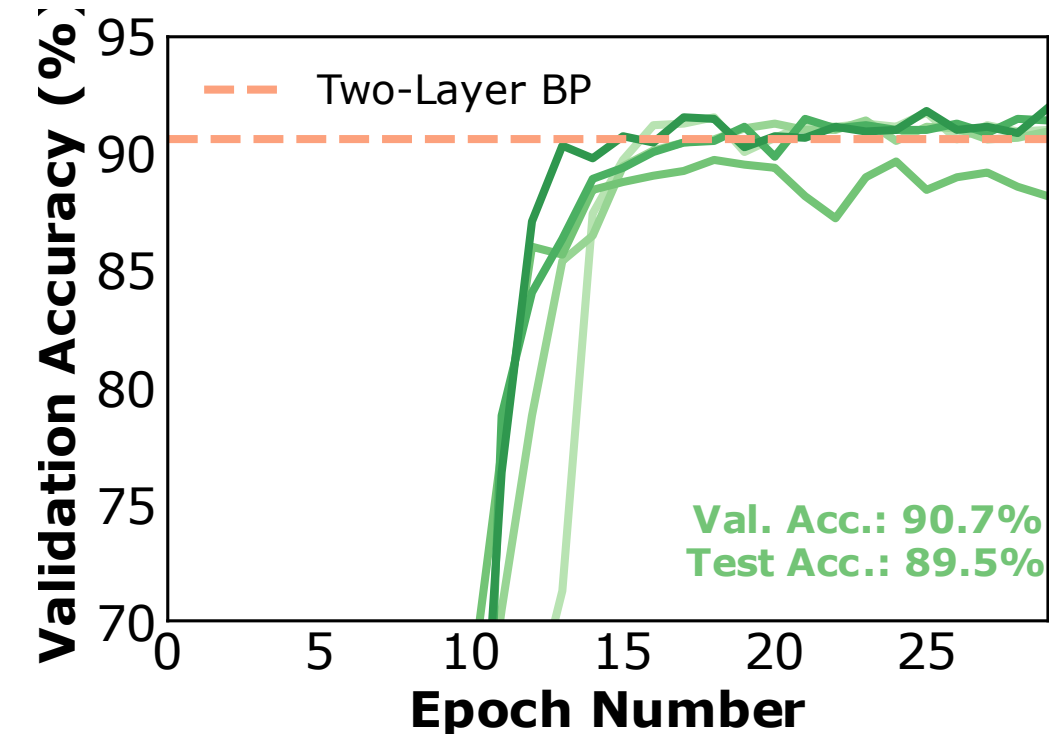
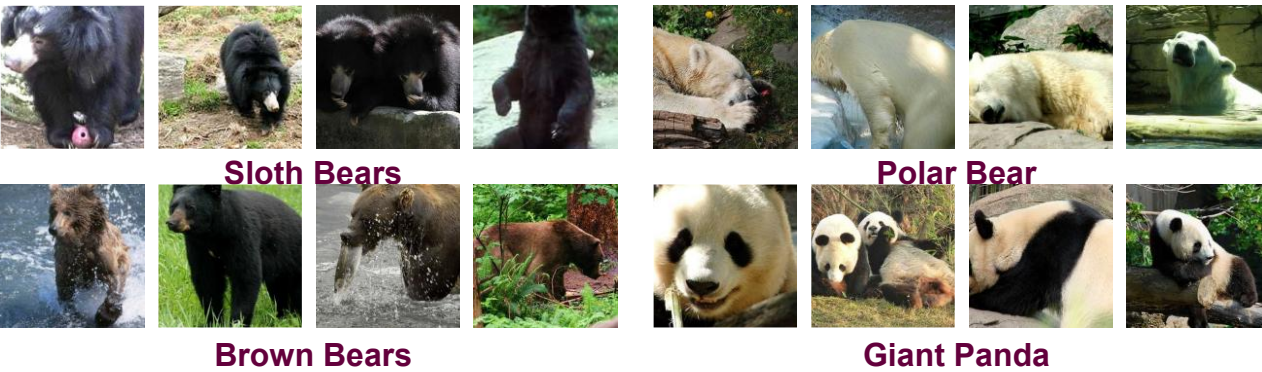
Learning With Memristor Low-Voltage Reset

Low voltage Reset is noisy, but:

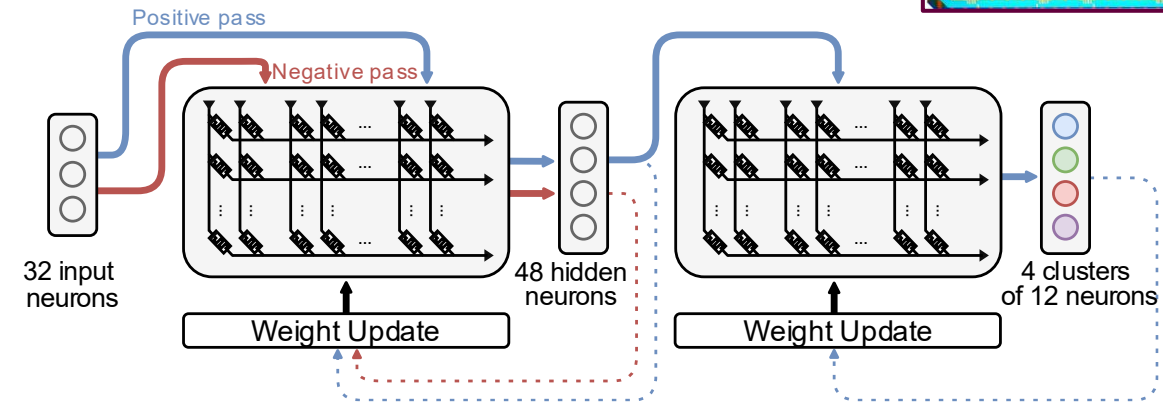
- Energy efficient ($<1V$, $<100ns$)
- Outstanding endurance
- Month-long retention



Learning to Classify Bears with 8,064 Memristors



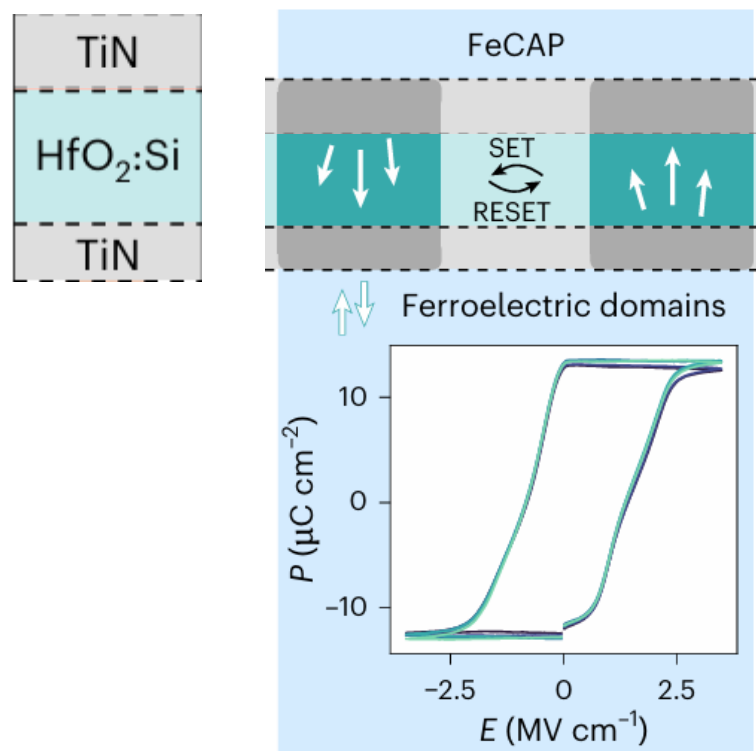
Supervised Forward-Forward (SFF)



Forward-only learning: learning using the same memristor-level operations than inference

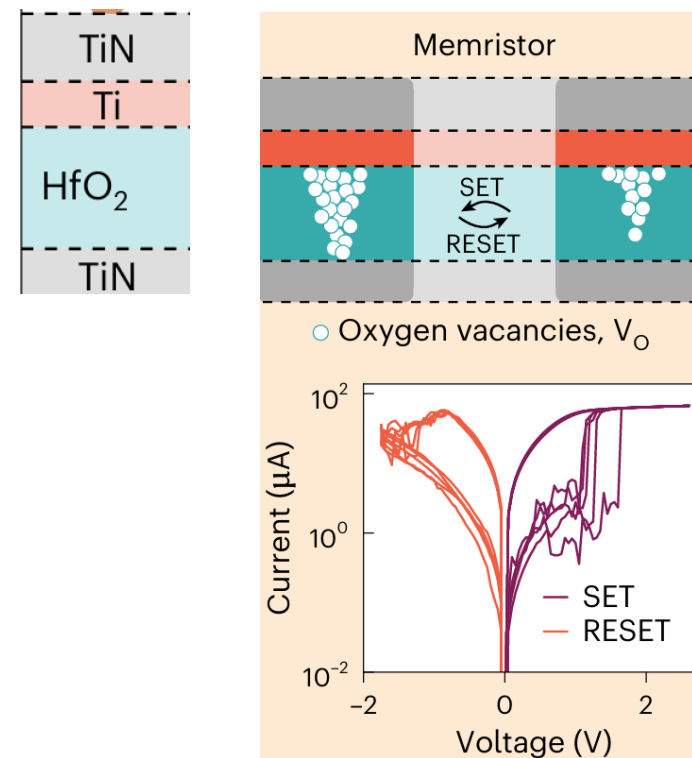
Hafnium Oxide Can Also Provide a Short Memory

Ferroelectric HfO₂



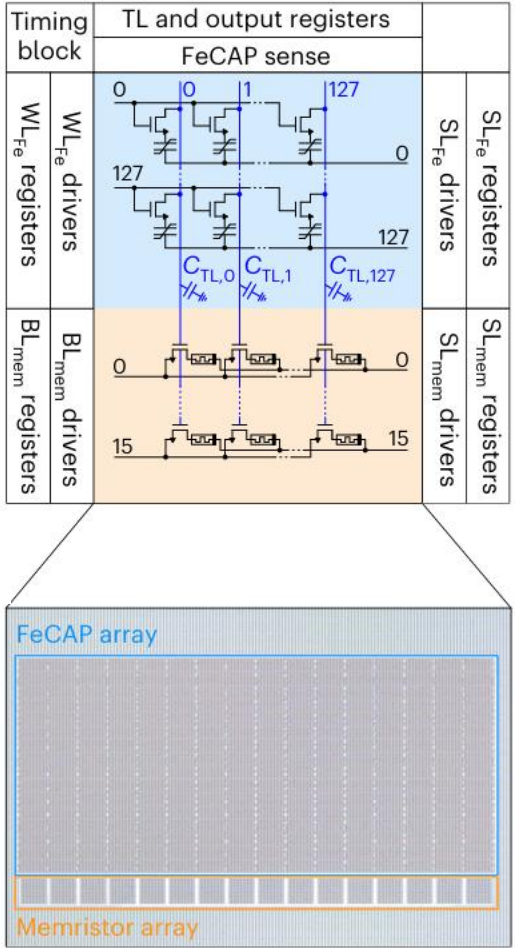
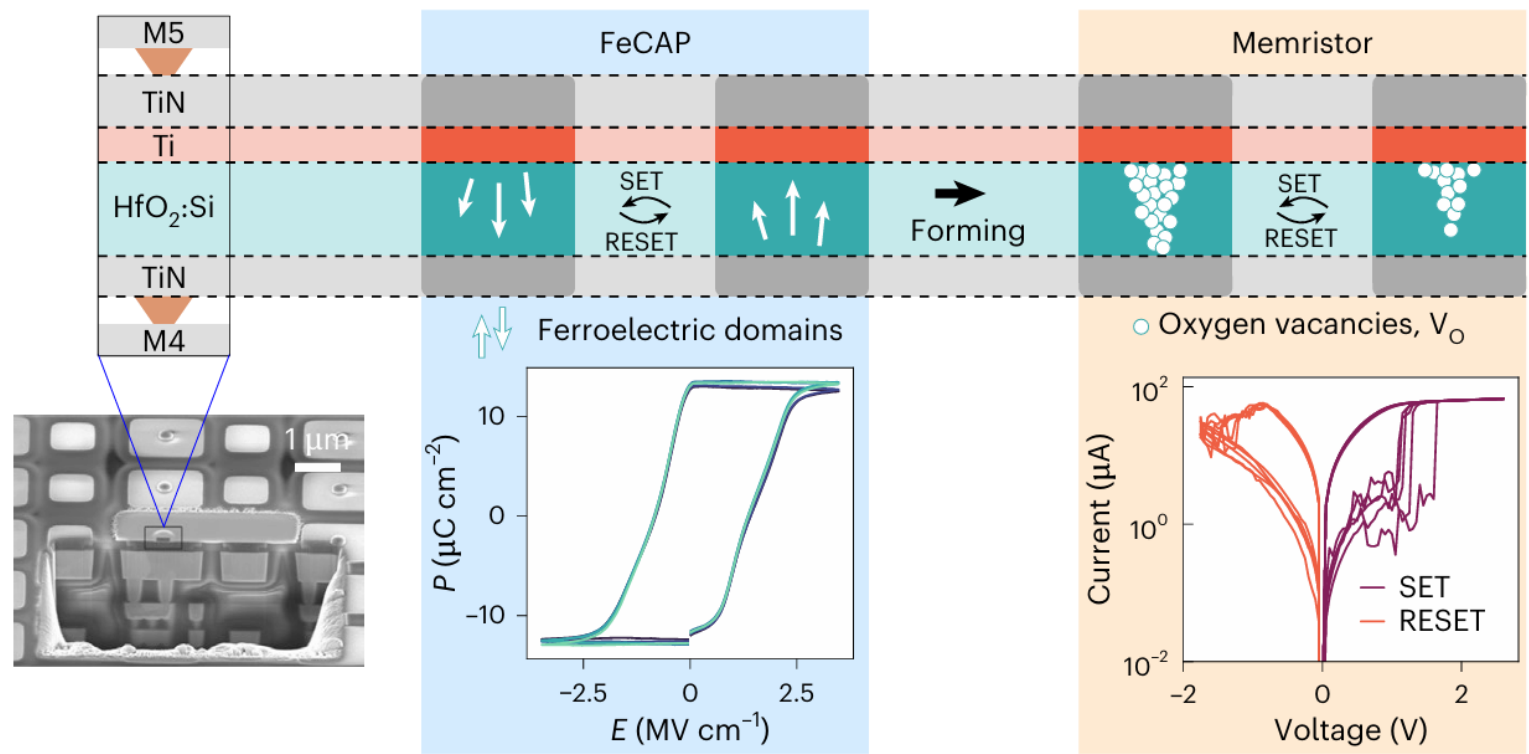
Ultra-low energy writes, outstanding endurance
Destructive read

Memristor HfO₂



Higher energy writes, lower endurance
Destructive read

The Ferroelectric-Memristor Memory

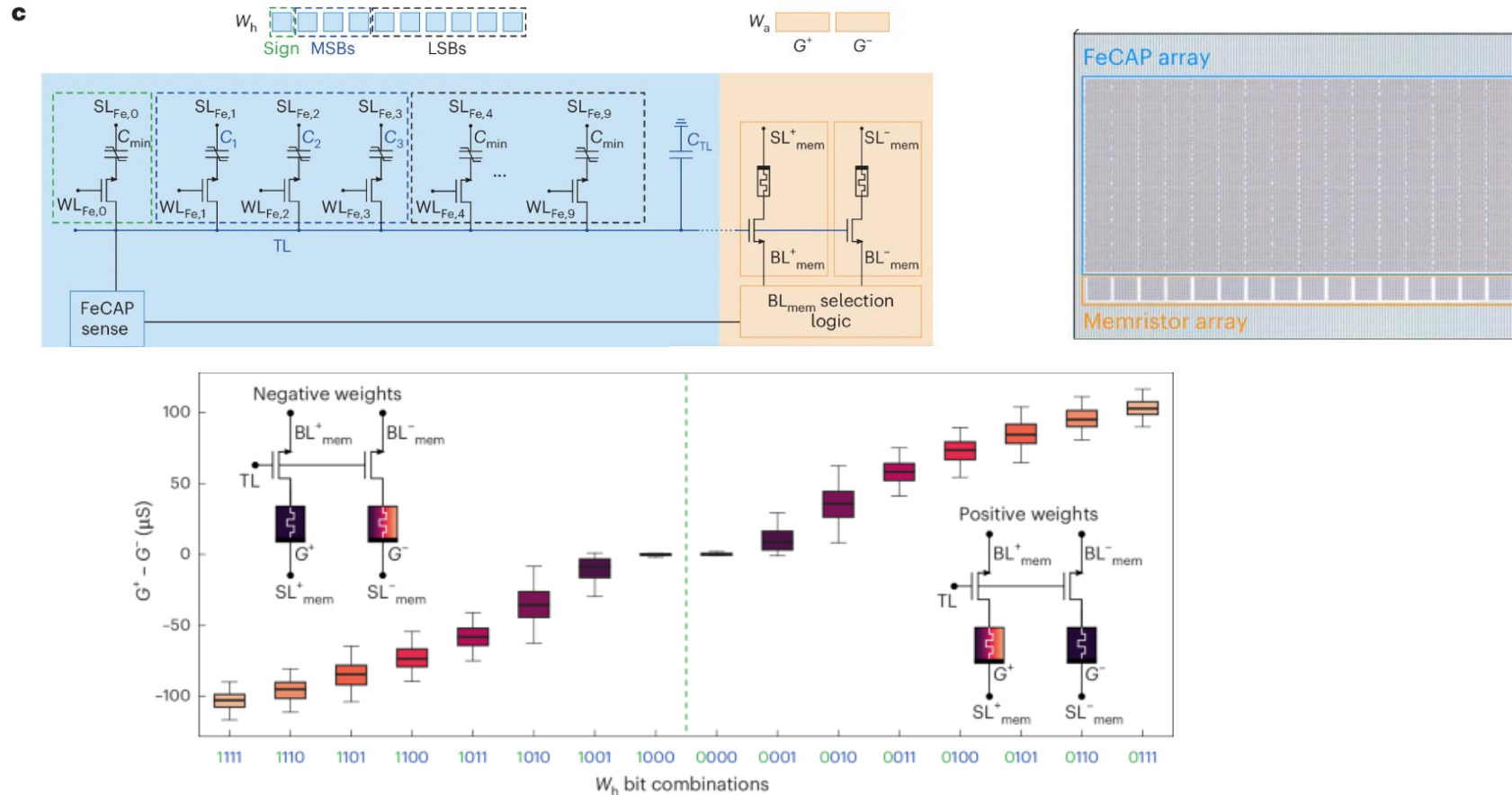


Collaboration



Martemucci et al, Nature Electronics 8, 921 (2025)

Information Can Be Transferred From Ferroelectric Short-Term to Memristor Long-Term Memory



Conclusion

- Computing with nanoelectronics devices: huge potential to reinvent electronics for low-power & trustworthy AI
- Interdisciplinary approach to electronics: codevelopment/codesign of technology, circuits, computer architecture and algorithms
- Current challenges: going 3D and moving toward genAI

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Thank you for your attention!

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